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Shinichi TANAKA, Aichi (JP)(21) Appl. No.: **15/746,929**(22) PCT Filed: **May 25, 2016**(86) PCT No.: **PCT/JP2016/065465**

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(57)

ABSTRACT

A display device includes a first substrate **11**, a second substrate **12**, and a plurality of light emitting elements **10**. Light is emitted via the second substrate **12**. Each of the light emitting elements **10** is formed by laminating, from a side of the first substrate, a first electrode **51**, an organic layer **70** having a light emitting layer, a second electrode **52**, and a sealing layer **15**. A light diffusion layer **80** containing fine particles **81** is formed between the sealing layer **15** and the second substrate **12**. Orthographic images of the fine particles **81** in the light diffusion layer **80** do not overlap each other on the second substrate **12**. Alternatively, the light diffusion layer is formed between the sealing layer and the second substrate, and the light diffusion layer includes a flat portion and a plurality of protruding portions each constituted by a part of a spherical surface protruding from the flat portion.

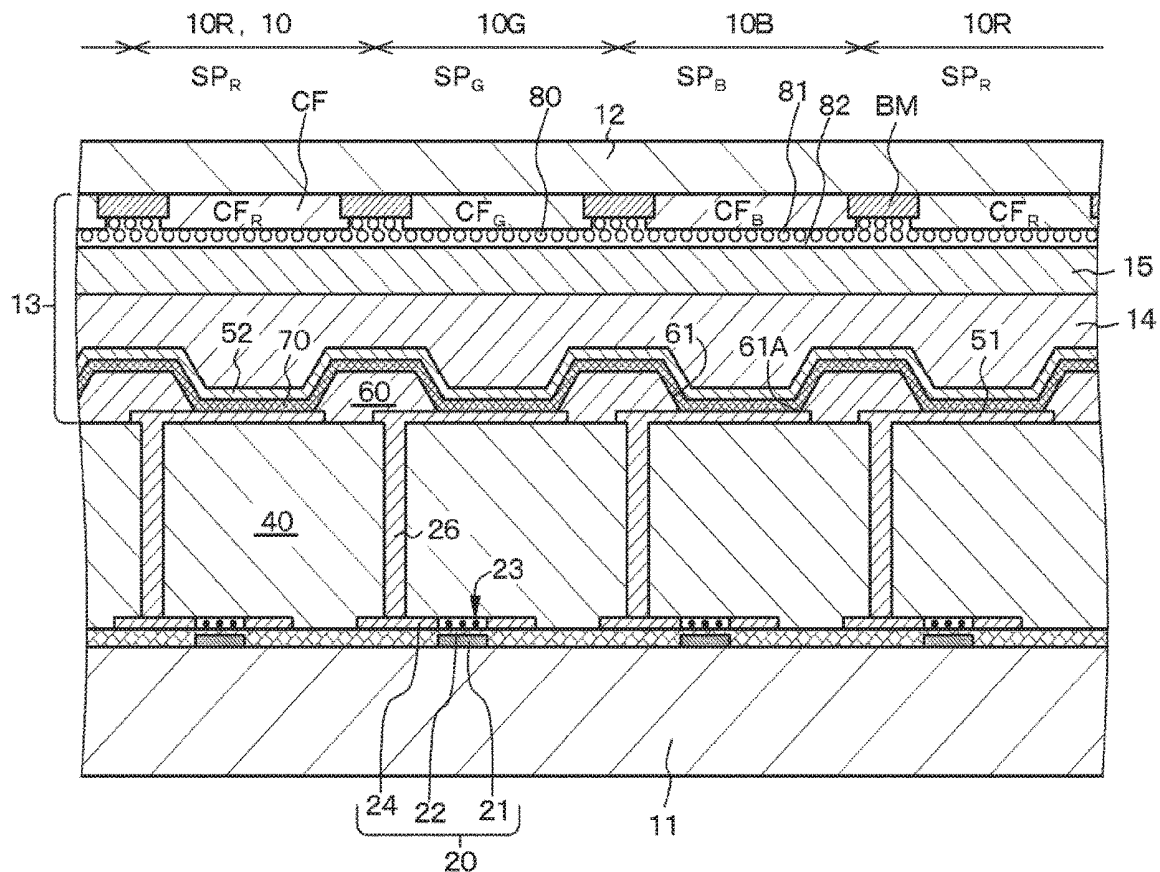


FIG. 2A

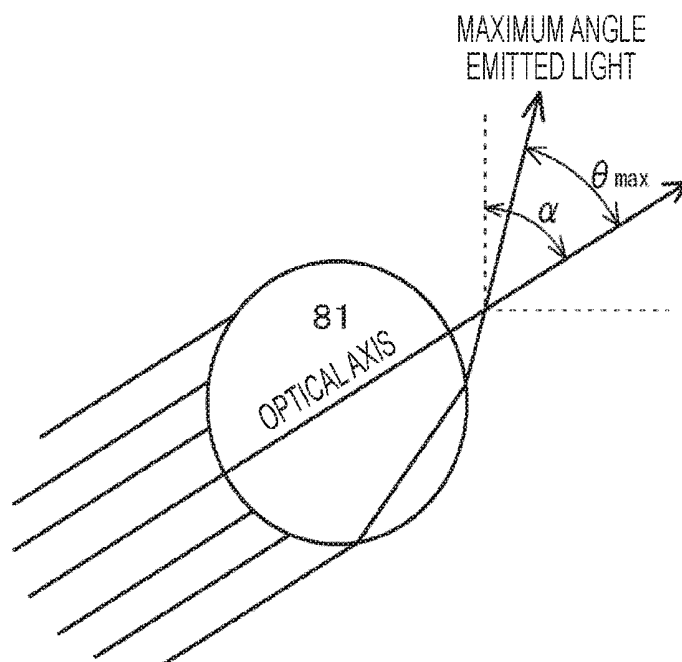


FIG. 2B

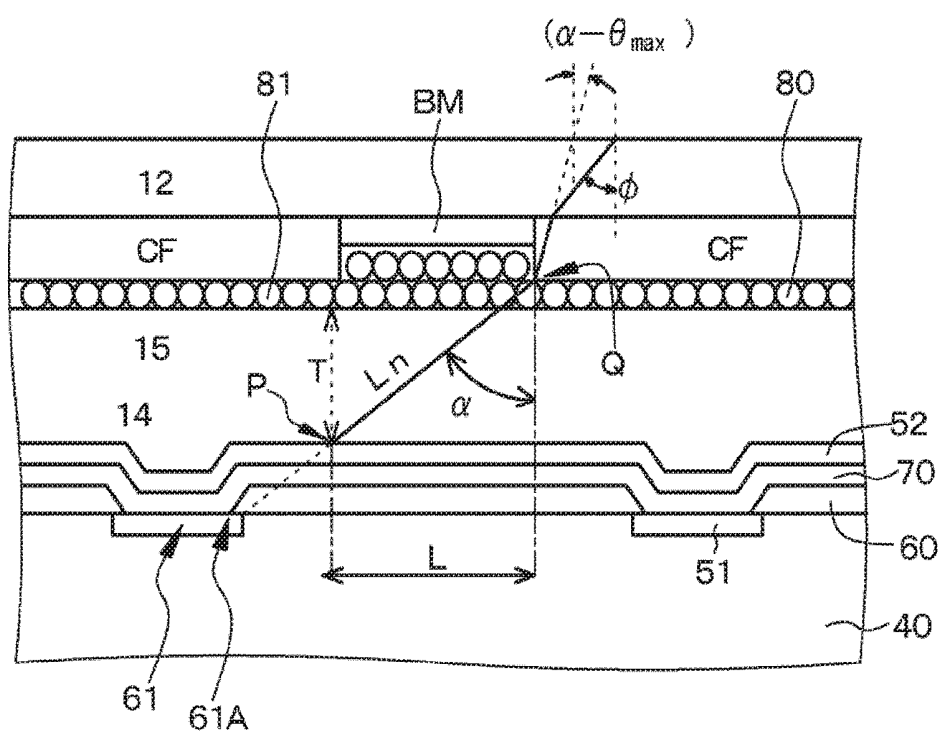


FIG. 3

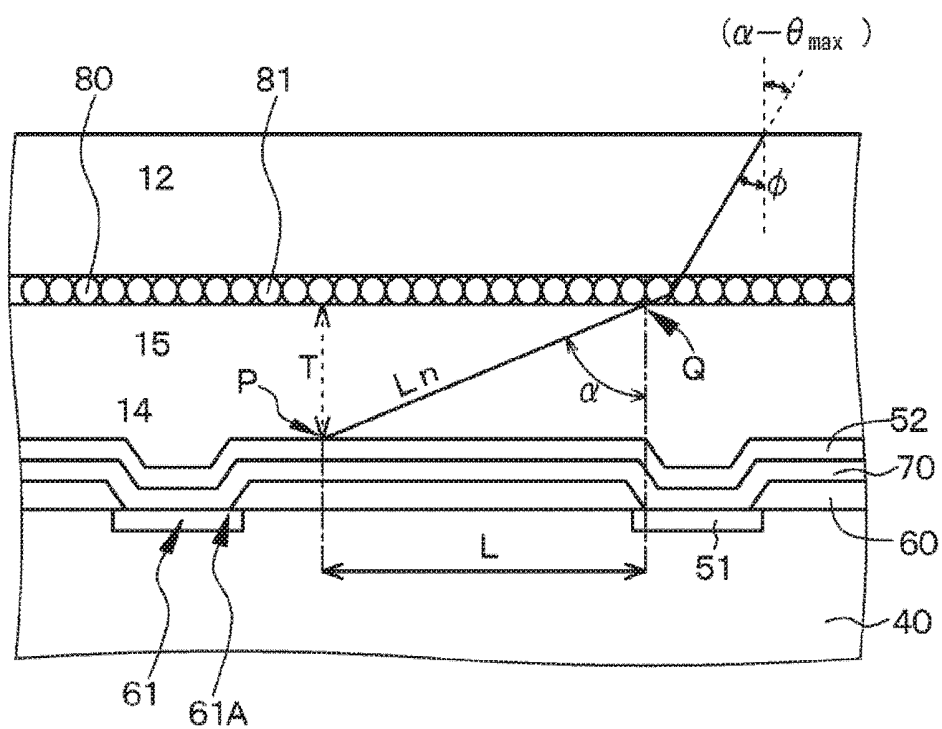
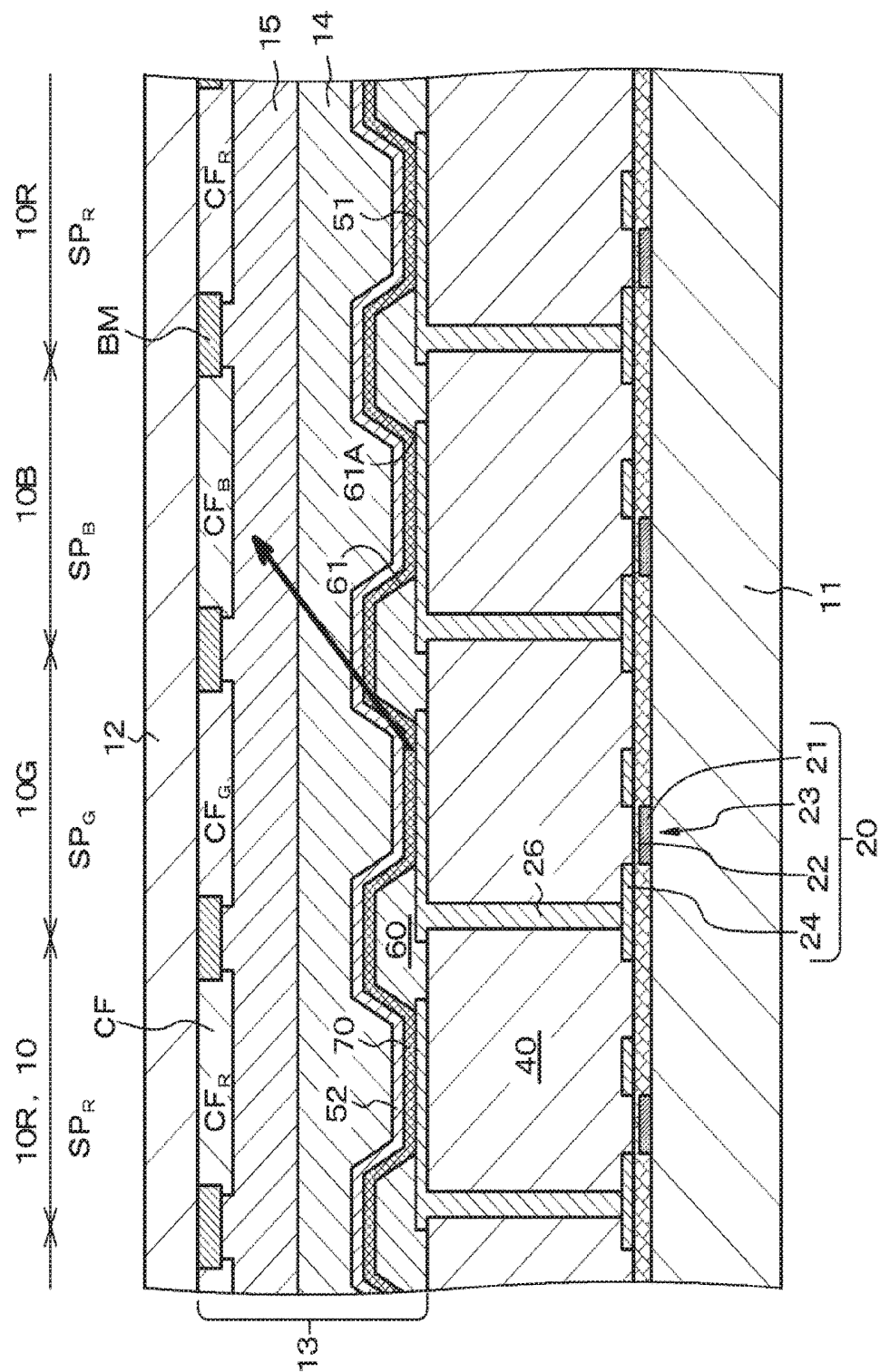


FIG. 7



DISPLAY DEVICE

TECHNICAL FIELD

[0001] The present disclosure relates to a display device.

BACKGROUND ART

[0002] As a display device for displaying an image, an organic electroluminescence display device (hereinafter, also simply abbreviated as an “organic EL display device”) using an organic electroluminescence element (hereinafter, also simply abbreviated as an “organic EL element”) as a light emitting element (display element) has been developed. In the display device, if reflection of external light is large, a display quality is deteriorated, and therefore it is necessary to suppress reflection of external light. Reflection of external light is roughly divided into two components. One of the components is a component of Fresnel reflection occurring at an interface between a member constituting an outermost surface of the display device and air, and the other component is a reflection component obtained by emission of light incident on the display device to an outside of the display device (hereinafter, this reflection component is abbreviated as a “reflection component”).

[0003] The organic EL display device has an organic EL element obtained by laminating a transparent electrode, an organic layer having a light emitting layer, and a metal electrode on a substrate. Therefore, light incident on the organic EL display device via the substrate passes through the transparent electrode and the organic layer, is reflected by the metal electrode, and is emitted to an outside of the organic EL display device. In addition, the light transmittance of constituent members other than a color filter layer is high, and therefore the light is emitted to the outside of the organic EL display device in a state where light is not sufficiently absorbed by the constituent members. Therefore, the reflection component increases.

[0004] Measures for reducing such a reflection component are well known from, for example, Japanese Patent Application Laid-Open No. 9-127885. In technology disclosed in this patent publication, a circular polarization unit is disposed on a side of a light emitting surface of a light emitting element.

[0005] Furthermore, light emitted from a light emitting layer is propagated in all directions. Therefore, as illustrated in a schematic partial cross-sectional view of FIG. 7, light emitted from a certain light emitting element (indicated by a thick solid line in FIG. 7) may enter a light emitting element adjacent to the certain light emitting element (referred to as an “adjacent light emitting element” for convenience), and may be emitted from the adjacent light emitting element to an outside. Note that such light is referred to as “light emitted from an adjacent light emitting element” for convenience. Regarding the reference signs in FIG. 7, refer to FIG. 1. As a result, deterioration in quality of a displayed image, such as image blur, bleeding, or resolution reduction may occur.

[0006] Technology for reducing such light emitted from an adjacent light emitting element is well known, for example, from Japanese Patent Application Laid-Open No. 2006-073219. In the technology disclosed in this patent publication, the thickness of a transparent resin layer is defined on

the basis of geometric distances among various members constituting a light emitting element, and refractive indices thereof.

CITATION LIST

Patent Document

[0007] Patent Document 1: Japanese Patent Application Laid-Open No. 9-127885

[0008] Patent Document 2: Japanese Patent Application Laid-Open No. 2006-073219

[0009] Patent Document 3: Japanese Patent Application Laid-Open No. 2010-186613

[0010] Patent Document 4: Japanese Patent Application Laid-Open No. 2014-191980

SUMMARY OF THE INVENTION

Problems to be Solved by the Invention

[0011] Technology disclosed in Japanese Patent Application Laid-Open No. 9-127885 is very effective for reducing a reflection component. However, due to use of the circular polarization unit, a half or more of light emitted from a light emitting layer is lost, power consumption increases, and a light emitting element may be deteriorated due to an increase in a current flowing in the light emitting element. Technology disclosed in Japanese Patent Application Laid-Open No. 2006-073219 can effectively reduce color leakage from an adjacent light emitting element, but has large restrictions on designing a light emitting element disadvantageously. Technology for providing a high refractive index uneven layer or a high refractive index resin layer containing particles in order to efficiently emit light emitted from a light emitting layer to an outside is known from Japanese Patent Application Laid-Open No. 2010-186613 or Japanese Patent Application Laid-Open No. 2014-192980, for example. However, these patent publications do not mention anything about technology for reducing light emitted from an adjacent light emitting element, and the high refractive index uneven layer or the high refractive index resin layer is formed so as to be in direct contact with a transparent electrode constituting a light emitting element. Therefore, it is difficult to prevent light from entering the adjacent light emitting element by the high refractive index uneven layer or the high refractive index resin layer.

[0012] Therefore, an object of the present disclosure is to provide a display device having a configuration and a structure capable of reducing a reflection component obtained by emission of light incident on the display device from an outside to the outside of the display device, and capable of effectively reducing light emitted from an adjacent light emitting element.

Solutions to Problems

[0013] A display device according to first and second aspects of the present disclosure for achieving the above object includes a first substrate, a second substrate, and a plurality of light emitting elements located between the first substrate and the second substrate and arranged in a two-dimensional matrix, and emits light via the second substrate. Each of the light emitting elements is formed by laminating,

from a side of the first substrate, a first electrode, an organic layer having a light emitting layer, a second electrode, and a sealing layer.

[0014] In addition, in the display device according to the first aspect of the present disclosure, a light diffusion layer containing particles is further formed between the sealing layer and the second substrate, and orthographic images of the particles in the light diffusion layer do not overlap each other on the second substrate. Incidentally, if the overlapping amount is 35% or less, preferably 30% or less, it can be said that orthographic images of the particles in the light diffusion layer do not overlap each other on the second substrate. Herein, the “overlapping amount” is represented by $\text{overlapping amount} = \{(L'/R) - 1\} \times 100(\%)$ if a particle is assumed to be a sphere having a diameter R , and a distance between centers of two particles is represented by L' in orthographic images of the two particles overlapping each other on the second substrate.

[0015] Furthermore, in the display device according to the second aspect of the present disclosure, a light diffusion layer is further formed between the sealing layer and the second substrate, and the light diffusion layer includes a flat portion and a plurality of protruding portions each constituted by a part of a spherical surface protruding from the flat portion.

Effects of the Invention

[0016] In the display device according to the first aspect of the present disclosure, the light diffusion layer containing particles is formed between the sealing layer and the second substrate, and therefore it is possible to reduce a reflection component obtained by emission of light incident on the display device from an outside to the outside of the display device. Furthermore, orthographic images of the particles in the light diffusion layer do not overlap each other on the second substrate. Therefore, each of the particles functions as a kind of lens. When light emitted from a certain light emitting element enters an adjacent light emitting element and is emitted from the adjacent light emitting element to an outside, a ratio of the light totally reflected on an outer surface of the second substrate and returning to the adjacent light emitting element is increased. As a result, it is possible to effectively reduce light emitted from the adjacent light emitting element, and it is possible to suppress occurrence of deterioration in quality of a displayed image, such as image blur, bleeding, or resolution reduction. If the particles overlap each other in the light diffusion layer, such a light diffusion layer becomes a kind of light scattering layer. It is difficult to reduce light emitted from the adjacent light emitting element, and deterioration in quality of a displayed image, such as image blur, bleeding, or resolution reduction easily occurs. In the display device according to the second aspect of the present disclosure, the light diffusion layer including a flat portion and a plurality of protruding portions is formed between the sealing layer and the second substrate. Therefore, it is possible to reduce a reflection component obtained by emission of light incident on the display device from an outside to the outside of the display device. Furthermore, the light diffusion layer includes a flat portion and a plurality of protruding portions each constituted by a part of a spherical surface. Therefore, each of the protruding portions functions as a kind of lens. When light emitted from a certain light emitting element enters an adjacent light emitting element and is emitted from the adjacent light

emitting element to an outside, a ratio of the light totally reflected on an outer surface of the second substrate and returning to the adjacent light emitting element is increased. As a result, it is possible to effectively reduce light emitted from the adjacent light emitting element, and it is possible to suppress occurrence of deterioration in quality of a displayed image, such as image blur, bleeding, or resolution reduction. Note that effects described herein are merely illustrative, and are not restrictive. In addition, an additional effect may be present.

BRIEF DESCRIPTION OF DRAWINGS

[0017] FIG. 1 is a schematic partial cross-sectional view of a display device of Example 1.

[0018] FIG. 2A and FIG. 2B are a model diagram when parallel light is incident on one particle and a diagram schematically illustrating behavior of light inside the display device of Example 1, respectively.

[0019] FIG. 3 is a diagram schematically illustrating behavior of light inside modification of the display device.

[0020] FIG. 4 is a schematic partial cross-sectional view of a display device of Example 2.

[0021] FIG. 5 is a schematic partial cross-sectional view of a display device of Example 3.

[0022] FIG. 6 is a schematic partial cross-sectional view of a modification example of the display device of Example 3.

[0023] FIG. 7 is a schematic partial cross-sectional view of a display device for explaining a problem of a conventional display device.

MODE FOR CARRYING OUT THE INVENTION

[0024] Hereinafter, the present disclosure will be described on the basis of Examples with reference to the drawings. However, the present disclosure is not limited to Examples, and various numerical values and materials in Examples are illustrative. Note that description will be made in the following order.

[0025] 1. General description of display devices according to first and second aspects of the present disclosure

[0026] 2. Example 1 (display device according to the first aspect of the present disclosure)

[0027] 3. Example 2 (display device according to the second aspect of the present disclosure)

[0028] 4. Example 3 (modification of Examples 1 and 2)

[0029] 5. Others

[0030] <General Description of Display Devices According to First and Second Aspects of the Present Disclosure>

[0031] In a display device according to a first aspect of the present disclosure, a particle is spherical and is regarded as a spherical lens (display device according to the first aspect of the present disclosure), or a protruding portion is regarded as a part of a spherical lens (display device according to a second aspect of the present disclosure). When a parallel light ray is incident on a spherical lens and is emitted from the spherical lens, if a maximum value of an angle formed by an optical axis of the spherical lens and the light ray emitted from the spherical lens (maximum angle) is represented by θ_{max} , an average distance between a second electrode and a light diffusion layer is represented by T , the shortest distance between light emitting elements adjacent to each other is represented by L , the refractive index of a medium in contact with the light diffusion layer on a side of

a second substrate is represented by n' , and the refractive index of air is represented by n_0 ,

[0032] $\alpha \geq \theta_{max} + \arcsin(n_0/n')$ is satisfied,

[0033] provided that $\tan(\alpha) = L/T$ is satisfied. By adopting these forms, when light emitted from a certain light emitting element enters an adjacent light emitting element and is emitted from the adjacent light emitting element to an outside, a ratio of the light totally reflected on an outer surface of the second substrate and returning to the adjacent light emitting element is further increased. Therefore, it is possible to more effectively reduce the light emitted from the adjacent light emitting element. In addition, in these cases, $\alpha \geq 0.9 \{\theta_{max} + \arcsin(n_0/n')\}$ is more preferably satisfied. The “medium in contact with a light diffusion layer on a side of a second substrate” means a color filter layer in a case where the color filter layer is formed between the light diffusion layer and the second substrate, and means the second substrate in a case where the light diffusion layer is formed on the second substrate.

[0034] Herein, the “shortest distance between light emitting elements adjacent to each other L ” means the shortest distance between an edge of a first electrode constituting a certain light emitting element and an edge of a first electrode constituting an adjacent light emitting element adjacent to the certain light emitting element in a case where the light diffusion layer is formed on the second substrate. Furthermore, in a case where the color filter layer is formed between the light diffusion layer and the second substrate, the “shortest distance L to an adjacent light emitting element” means the shortest horizontal distance from a point where a second electrode intersects with the shortest straight line connecting an edge of a first electrode constituting a certain light emitting element and an edge of the color filter layer constituting an adjacent light emitting element adjacent to the certain light emitting element to the edge of the color filter layer constituting the adjacent light emitting element. The “optical axis of a spherical lens” means a parallel light ray incident on the spherical lens, and coincides with a light ray passing through the center of the spherical lens. The “orthographic images of particles” means a shadow of particles obtained on the second substrate when the particles are irradiated with a parallel light ray perpendicular to the second substrate. The maximum angle θ_{max} is a value depending on the refractive index of a material constituting a particle and a protruding portion and the refractive index of a material constituting a transparent material layer described below.

[0035] In the display device according to the first aspect of the present disclosure including the above preferable forms, the particle is spherical and the diameter of the particle may be $1/10$ or more of the wavelength of light emitted from a light emitting layer. In the display device according to the second aspect of the present disclosure including the above preferable forms, the diameter of a part of a spherical surface constituting a protruding portion may be $1/10$ or more of the wavelength of light emitted from a light emitting layer. By adopting these configurations, in a particle or a protruding portion, Rayleigh scattering is no longer dominant (that is, back scattering is reduced), and it is possible to suppress a decrease in luminous efficiency of a light emitting element. In addition, in these configurations, the diameter of a part of a spherical surface constituting a protruding portion is preferably not more than the wavelength of light emitted from a light emitting layer. By adopting such a configura-

tion, in the protruding portion, Mie scattering is no longer dominant (that is, light is hardly observed as light spreading to the surroundings). It is possible to suppress occurrence of image bleeding, resolution reduction, or sharpness reduction more reliably. Furthermore, in the display device according to the first aspect of the present disclosure including the above-described preferable forms and configurations, $1 < t/R < 2$ is preferably satisfied when the thickness of a light diffusion layer is represented by t and the diameter of a particle is represented by R . Herein, the “wavelength of light emitted from a light emitting layer” is defined as a maximum wavelength (for example, 650 nm) of the wavelength of visible light. The diameter of a part of a spherical surface constituting a protruding portion can be measured using a scanning electron microscope, for example.

[0036] In the display devices according to the first and second aspects of the present disclosure including the above-described preferable forms and configurations, area variation of orthographic images of the particles in the light diffusion layer on the second substrate based on an effective area of the light emitting elements can be within 3%. Alternatively, area variation of the protruding portions based on an effective area of the light emitting elements can be within 3%. A ratio of the total area of the orthographic images of the particles in the light diffusion layer on the second substrate based on an effective area of the light emitting elements corresponds to a particle occupancy ratio. Herein, the “effective area of the light emitting elements” means the area of a portion of the first electrode in contact with the organic layer constituting each of the light emitting elements in a case where the light diffusion layer is formed on the second substrate. Furthermore, the “effective area of the light emitting element” means the area of a color filter layer in a case where the color filter layer is formed between the light diffusion layer and the second substrate. The “area variation” is determined as follows. That is, in each of nine regions of a region near an upper right corner of an image display region of the display device, a region near the center of an upper side, a region near an upper left corner, a region near the center of a right side, an image display region, a region near the center of a left side, a region near a lower right corner, a region near the center of a lower side, and a region near a lower upper corner, ten light emitting elements are selected. In each of the 90 light emitting elements in total, a total area S_1 of the orthographic images of the particles in the light diffusion layer on the second substrate is determined, or a total area S_1' of the protruding portions is determined, and a coefficient of variation CV (standard deviation/average value) is determined from an average value and a standard deviation of S_1 or S_1' . The value of the coefficient of variation CV is taken as the area variation. The condition that the area variation is within 3% was obtained as a result of various experiments. If the total area of the orthographic images of the particles in the light diffusion layer on the second substrate or the total area of the protruding portions based on an effective area of the light emitting elements varies between the light emitting elements, a lens effect of the light diffusion layer varies, and the display device is visually recognized as glare that the display device is partially bright. As a result of experiments, it has been found that this glare is recognized in a case where the particle occupancy ratio in the light emitting element or the variation in the total area of the protruding portions exceeds 3%. In order to suppress this area variation, it is important

that several or more particles or protrusions exist in the light emitting element. It is only required to determine the number of particles or protrusions in each of the light emitting elements on the basis of the diameters of the particles or the protrusions and the desired density of the particles or the protrusions (the number of particles or protrusions per effective area of the light emitting elements).

[0037] In the display device according to the first aspect of the present disclosure including the above-described preferable forms and configurations, $S_1/S_0 \leq 0.9$ is preferably satisfied when the total area of the orthographic images of the particles in the light diffusion layer on the second substrate is represented by S_1 , and the effective area of the light emitting elements is represented by S_0 . Furthermore, in the display device according to the second aspect of the present disclosure including the above-described preferable forms and configurations, $S_1'/S_0 \leq 0.9$ is preferably satisfied when the total area of the protruding portions is represented by S_1' , and the effective area of the light emitting elements is represented by S_0 . Note that examples of a lower limit value of S_1/S_0 and a lower limit value of S_1'/S_0 include 0.1.

[0038] In the display devices according to the first and second aspects of the present disclosure including the above-described preferable forms and configurations, the color filter layer is formed between the light diffusion layer and the second substrate, and a light shielding layer can be formed between the color filter layer and the color filter layer. The color filter layer and the light shielding layer are formed on the second substrate.

[0039] Examples of a material constituting the particles in the display device according to the first aspect of the present disclosure include: an inorganic material such as titanium oxide (TiO_2), barium titanate (BaTiO_3), ZnS , ZrO_2 , ZnO , glass, a quartz-based material such as silicon oxide, silicon nitride, aluminum oxide, barium oxide, or barium sulfate; and an organic material such as an acrylic resin, a polymethyl methacrylate-based resin, a divinylbenzene-based resin, a benzoguanamine-based resin, a styrene-based resin, a melamine-based resin, an acryl-styrene copolymer-based resin, a polycarbonate-based resin, a polyethylene-based resin, a polyvinyl chloride-based resin, or a silicone-based resin. Furthermore, in the light diffusion layer in the display device according to the first aspect of the present disclosure, a space between the particles is filled with a transparent material layer. Examples of a material constituting the transparent material layer include an acrylic resin. When the refractive index of a material constituting the particles is represented by n_{11} and the refractive index of a material constituting the transparent material layer is represented by n_{12} , $|n_{11} - n_{12}| \geq 0.1$ is preferably satisfied. In the light diffusion layer in the display device according to the second aspect of the present disclosure, examples of a material constituting the flat portion and the protruding portions include a sealing resin, an overcoating resin, and an inorganic dielectric material. Furthermore, in the light diffusion layer in the display device according to the second aspect of the present disclosure, the protruding portions are filled with the transparent material layer. Examples of a material constituting the transparent material layer include an acrylic resin. When the refractive index of a material constituting the flat portion and the protruding portions is represented by n_{21} and the refractive index of a material constituting the transparent material layer is represented by n_{22} , $|n_{21} - n_{22}| \geq 0.1$ is preferably satisfied. Note that the particle

regarded as a spherical lens and the protruding portion regarded as a part of a spherical lens may function as a convex lens having positive optical power, or may function as a concave lens having negative optical power depending on a relationship between the refractive indices n_{11} and n_{21} of materials constituting the particle and the protruding portion, and the refractive indices n_{12} and n_{22} of the transparent material layer.

[0040] Specific examples of a method for forming the light diffusion layer in the display device according to the first aspect of the present disclosure include a method for applying a photosensitive resin having spherical particles of SiO_2 or the like dispersed therein and curing the photosensitive resin.

[0041] In the light diffusion layer of the display device according to the second aspect of the present disclosure, specific examples of a method for forming the protruding portion and the flat portion include a method for forming or disposing a protruding portion on a supporting substrate, and transferring the protruding portion to the second substrate (when the protruding portion is transferred to the second substrate, the protruding portion is peeled from the supporting substrate), and a combination of photolithography technology and etching technology.

[0042] The display devices according to the first and second aspects of the present disclosure including the above-described various preferable forms and configurations (hereinafter, these are collectively referred to as “the display device of the present disclosure or the like”) are top emission type display devices that emit light from the second substrate. In addition, the display device has a plurality of light emitting elements, but each of the light emitting elements constitutes a sub-pixel. Furthermore, the organic EL element can constitute the light emitting element. The light emitting layer may be constituted by at least two light emitting layers that emit different colors. In this case, light emitted from the organic layer may be white. Specifically, the light emitting layer may have a structure obtained by laminating three layers of a red light emitting layer that emits red light (wavelength: 620 nm to 750 nm), a green light emitting layer that emits green light (wavelength: 495 nm to 570 nm), and a blue light emitting layer that emits blue light (wavelength: 450 nm to 495 nm), and emits white light as a whole. Alternatively, the light emitting layer may have a structure obtained by laminating two layers of a blue light emitting layer that emits blue light and a yellow light emitting layer that emits yellow light, and emits white light as a whole. Alternatively, the light emitting layer may have a structure obtained by laminating two layers of a blue light emitting layer that emits blue light and an orange light emitting layer that emits orange light, and emits white light as a whole. In addition, such a white light emitting element that emits white light includes a red color filter layer to constitute a red light emitting element. The white light emitting element includes a green color filter layer to constitute a green light emitting element. The white light emitting element includes a blue color filter layer to constitute a blue light emitting element. One pixel is constituted by a red light emitting element, a green light emitting element, and a blue light emitting element. In some cases, one pixel may be constituted by a red light emitting element, a green light emitting element, a blue light emitting element, and a light emitting element that emits white light (or a light emitting element that emits complementary color light). Note that, in the

above form constituted by at least two light emitting layers that emit light of different colors, there is actually a case where the light emitting layers that emit light of different colors are mixed and are not clearly separated into the layers. Alternatively, one pixel may be constituted by three sub-pixels (light emitting elements) of a sub-pixel having a red light emitting layer and constituted by a light emitting element that emits red light, a sub-pixel having a green light emitting layer and constituted by a light emitting element that emits green light, and a sub-pixel having a blue light emitting layer and constituted by a light emitting element that emits blue light. Alternatively, one pixel may be constituted by four sub-pixels (light emitting elements) of a sub-pixel having a red light emitting layer and constituted by a light emitting element that emits red light, a sub-pixel having a green light emitting layer and constituted by a light emitting element that emits green light, a sub-pixel having a blue light emitting layer and constituted by a light emitting element that emits blue light, and a sub-pixel constituted by a light emitting element that emits white light (or a light emitting element that emits complementary color light).

[0043] The first substrate or the second substrate may be constituted by a high strain point glass substrate, a soda glass ($\text{Na}_2\text{O} \cdot \text{CaO} \cdot \text{SiO}_2$) substrate, a borosilicate glass ($\text{Na}_2\text{O} \cdot \text{B}_2\text{O}_3 \cdot \text{SiO}_2$) substrate, a forsterite ($2\text{MgO} \cdot (\text{SiO}_2)$) substrate, a lead glass ($\text{Na}_2\text{O} \cdot \text{PbO} \cdot \text{SiO}_2$) substrate, various glass substrates each having an insulating film formed on a surface thereof, a quartz substrate, a quartz substrate having an insulating film formed on a surface thereof, a silicon semiconductor substrate, or an organic polymer such as polymethyl methacrylate (PMMA), polyvinyl alcohol (PVA), polyvinyl phenol (PVP), polyether sulfone (PES), polyimide, polycarbonate, or polyethylene terephthalate (PET) (having a form of a polymer material such as a plastic film, a plastic sheet, or a plastic substrate constituted by a polymer material and having flexibility). Materials constituting the first substrate and the second substrate may be the same as or different from each other. However, the second substrate is required to be transparent to light emitted from the light emitting element.

[0044] In a case where the first electrode is caused to function as an anode electrode, examples of a material constituting the first electrode include aluminum (Al) and an alloy containing aluminum, and a metal having high work function, such as platinum (Pt), gold (Au), silver (Ag), chromium (Cr), molybdenum (Mo), titanium (Ti), tungsten (W), nickel (Ni), copper (Cu), iron (Fe), cobalt (Co), or tantalum (Ta), or an alloy thereof (for example, an Ag—Pd—Cu alloy containing silver as a main component and containing 0.3% by mass to 1% by mass of palladium (Pd) and 0.3% by mass to 1% by mass of copper (Cu), an Al—Nd alloy, or an Al—Ni alloy). The thickness of the first electrode may be 0.1 μm to 1 μm , for example. Alternatively, the material constituting the first electrode may be a transparent conductive material having excellent hole injection characteristics, such as an oxide of indium and tin (ITO) or an oxide of indium and zinc (IZO), or may have a structure obtained by laminating a transparent conductive material having excellent hole injection characteristics, such as an oxide of indium and tin (ITO) or an oxide of indium and zinc (IZO) on a dielectric multilayer film or a reflective film having high light reflectivity, including aluminum (Al) or the like. Meanwhile, in a case where the first electrode is caused to function as a cathode electrode, the first electrode is

desirably constituted by a conductive material having a small work function value and high light reflectivity. However, by improving an electron injection property, for example, by disposing an appropriate electron injection layer in a conductive material having high light reflectivity used as an anode electrode, the resulting conductive material can also be used as a cathode electrode.

[0045] Meanwhile, in a case where the second electrode is caused to function as a cathode electrode, a material constituting the second electrode (a semi-light transmitting material or a light transmitting material) is desirably constituted by a conductive material having a small work function value so as to be able to transmit emitted light and inject an electron into an organic layer efficiently. Examples of the material constituting the second electrode include a metal having a small work function and an alloy thereof, such as aluminum (Al), silver (Ag), magnesium (Mg), calcium (Ca), sodium (Na), strontium (Sr), an alkali metal or an alkaline earth metal and silver (Ag) [for example, an alloy of magnesium (Mg) and silver (Ag) (Mg—Ag alloy)], an alloy of magnesium-calcium (Mg—Ca alloy), or an alloy of aluminum (Al) and lithium (Li) (Al—Li alloy). Among these materials, an Mg—Ag alloy is preferable, and a volume ratio between magnesium and silver may be Mg:Ag=5:1 to 30:1, for example. Alternatively, as a volume ratio between magnesium and calcium may be Mg:Ca=2:1 to 10:1, for example. The thickness of the second electrode may be 4 nm to 50 nm, preferably 4 nm to 20 nm, and more preferably 6 nm to 12 nm, for example. Alternatively, the second electrode may have a laminated structure of the above material layer and a so-called transparent electrode (for example, thickness 3×10^{-8} m to 1×10^{-6} m) including, for example, ITO or IZO, from the organic layer. A bus electrode (auxiliary electrode) including a low resistance material such as aluminum, an aluminum alloy, silver, a silver alloy, copper, a copper alloy, gold, or a gold alloy may be disposed in the second electrode to reduce resistance as a whole of the second electrode. Meanwhile, in a case where the second electrode is caused to function as an anode electrode, the second electrode is desirably constituted by a conductive material that transmits emitted light and has a large work function value. Average light transmittance of the second electrode is 50% to 90%, and preferably 60% to 90%.

[0046] Examples of a method for forming the first electrode or the second electrode include a combination of a vapor deposition method including an electron beam vapor deposition method, a hot filament vapor deposition method, and a vacuum vapor deposition method, a sputtering method, a chemical vapor deposition method (CVD method), an MOCVD method, and an ion plating method with an etching method; various printing methods such as a screen printing method, an inkjet printing method, and a metal mask printing method; a plating method (an electroplating method or an electroless plating method); a lift-off method; a laser ablation method; and a sol-gel method. According to various printing methods and a plating method, the first electrode or the second electrode having a desired shape (pattern) can be formed directly. Note that, in a case where the second electrode is formed after the organic layer is formed, the second electrode is preferably formed particularly on the basis of a film formation method in which energy of film formation particles is small, such as a vacuum vapor deposition method, or a film formation method such

as an MOCVD method from a viewpoint of preventing the organic layer from being damaged. When the organic layer is damaged, non-light emitting pixels (or non-light emitting sub-pixels) called "dark spots" due to generation of a leak current may be generated. In addition, processes from formation of the organic layer to formation of these electrodes are preferably performed without exposure thereof to the atmosphere from a viewpoint of preventing deterioration of the organic layer due to moisture in the atmosphere. In some cases, the second electrode does not need to be patterned, and may be a so-called common electrode.

[0047] The organic layer includes a light emitting layer including an organic light emitting material. Specifically, for example, the organic layer may be constituted by a laminated structure of a hole transport layer, a light emitting layer, and an electron transport layer, a laminated structure of a hole transport layer and a light emitting layer serving also as an electron transport layer, or a laminated structure of a hole injection layer, a hole transport layer, a light emitting layer, an electron transport layer, and an electron injection layer. The light emitting layer may be constituted by a single light emitting layer that emits light of a single color, or may be constituted by a plurality of light emitting layers that emits light of a plurality of colors, as described above. In addition, an organic layer that emits white light as a whole can be obtained. However, in the latter case, as described above, there are cases where it cannot be clearly recognized that the light emitting layer is constituted by a plurality of light emitting layers. In addition, in a case where these laminated structures and the like are formed into a "tandem unit", the organic layer may have a tandem structure with two stages obtained by laminating a first tandem unit, a connection layer, and a second tandem unit. Furthermore, the organic layer may have a tandem structure with three or more stages obtained by laminating three or more tandem units. In these cases, by making an emission color such as red, green, or blue different among the tandem units, an organic layer that emits white light as a whole can be obtained. Examples of a method for forming the organic layer include a physical vapor deposition method (PVD method) such as a vacuum vapor deposition method; a printing method such as a screen printing method or an inkjet printing method; a laser transfer method in which an organic layer on a laser absorption layer is separated by irradiating a laminated structure of a laser absorption layer and an organic layer formed on a transfer substrate with a laser and the organic layer is transferred, and various coating methods. In a case where the organic layer is formed on the basis of the vacuum vapor deposition method, for example, using a so-called metal mask, the organic layer can be obtained by depositing a material that has passed through an opening disposed in the metal mask, or the organic layer may be formed on the entire surface without patterning.

[0048] Examples of a material constituting the sealing layer include a thermosetting adhesive such as an acrylic adhesive, an epoxy-based adhesive, a urethane-based adhesive, a silicone-based adhesive, or a cyanoacrylate-based adhesive, and an ultraviolet curable adhesive.

[0049] An insulating or conductive protective film is preferably disposed on the second electrode, that is, between the second electrode and the sealing layer in order to prevent moisture from reaching the organic layer. The protective film is preferably formed particularly on the basis of a film formation method in which the energy of film formation

particles is small, such as a vacuum vapor deposition method, or a film formation method such as a CVD method or an MOCVD method because an influence on a base can be reduced. Alternatively, in order to prevent degradation of brightness due to deterioration of the organic layer, a film formation temperature is desirably set to room temperature. Furthermore, in order to prevent peeling of the protective film, the protective film is desirably formed under a condition minimizing a stress of the protective film. In addition, the protective film is preferably formed without exposure of an already formed electrode to the atmosphere. As a result, deterioration of the organic layer due to moisture or oxygen in the atmosphere can be prevented. Furthermore, the protective film is desirably constituted by a material that transmits light generated in the organic layer by, for example, 80% or more. Specific examples of the material include an inorganic amorphous insulating material such as the following materials. Such an inorganic amorphous insulating material does not generate grains, and therefore has low water permeability and constitutes a good protective film. Specifically, as a material constituting the protective film, a material that is transparent to light emitted from the light emitting layer, is dense, and does not transmit moisture is preferably used. More specific examples of the material include amorphous silicon (α -Si), amorphous silicon carbide (α -SiC), amorphous silicon nitride (α -Si_{1-x}N_x), amorphous silicon oxide (α -Si_{1-x}O₃), amorphous carbon (α -C), amorphous silicon oxide/nitride (α -SiON), and Al₂O₃. In a case where the protective film is constituted by a conductive material, the protective film is only required to be constituted by a transparent conductive material such as ITO or IZO.

[0050] The protective film and the light diffusion layer are bonded by the sealing layer. A planarization film may be formed between the light diffusion layer and the sealing layer. Furthermore, in the display device according to the first aspect of the present disclosure, the planarization film may be formed between the light diffusion layer and the second substrate (or the color filter layer and the light shielding layer).

[0051] The color filter layer is constituted by a resin to which a coloring agent containing a desired pigment or dye is added. By selecting a pigment or a dye, adjustment is performed such that light transmittance in a target wavelength range of red, green, blue, or the like is high, and light transmittance in the other wavelength ranges is low. For a light emitting element that emits white light, it is only required to dispose a transparent filter layer. As described above, the light shielding layer (black matrix layer) is formed between the color filter layer and the color filter layer. For example, the light shielding layer is constituted by a black resin film (specifically, including a black polyimide resin, for example) having an optical density of 1 or more, mixed with a black coloring agent, or a thin film filter using interference of a thin film. The thin film filter is formed by laminating two or more thin films including metal, metal nitride, or metal oxide, for example, and attenuates light by utilizing interference of a thin film. Specific examples of the thin film filter include a thin film filter obtained by alternately laminating Cr and chromium(III) oxide (Cr₂O₃). In a portion of the light diffusion layer including the particles overlapping with the light shielding layer, orthographic

images of the particles in the light diffusion layer do not have to overlap or may overlap each other on the second substrate.

[0052] In the display device, the first electrode is disposed on an interlayer insulation layer, for example. In addition, this interlayer insulation layer covers a light emitting element driving unit formed on the first substrate (or the first substrate). The light emitting element driving unit is constituted by one or more transistors (for example, MOSFETs or TFTs). The transistors are electrically connected to the first electrode via a contact hole (contact plug) disposed in the interlayer insulation layer. The light emitting element driving unit can have a known circuit configuration. As a constituent material of the interlayer insulation layer, an SiO₂-based material such as SiO₂, BPSG, PSG, BSG, AsSG, PbSG, SOG (spin on glass), low melting point glass, or glass paste; an SiN-based material including an SiON-based material; or an insulating resin such as an acrylic resin or a polyimide resin can be used singly or in combination thereof appropriately. For forming the interlayer insulation layer, a known process such as a CVD method, a coating method, a sputtering method, or various printing methods can be used.

[0053] A structure may be employed in which an insulation layer may be formed on the interlayer insulation layer and the first electrode, an opening may be disposed in the insulation layer on the first electrode, and the first electrode may be exposed to a bottom of the opening. The organic layer is formed over the insulation layer from above the first electrode exposed to a bottom of the opening. Alternatively, the insulation layer may be formed on the interlayer insulation layer exposed between the first electrode and the first electrode. The organic layer is formed over the insulation layer from above the first electrode. The insulation layer may be constituted by a material constituting the above interlayer insulation layer. The material constituting the insulation layer and the material constituting the interlayer insulation layer may be the same as or different from each other. Usually, an edge of the opening corresponds to an edge of a portion of the first electrode in contact with the organic layer.

[0054] The organic EL display device may have a resonator structure in order to further improve light extraction efficiency. Specifically, light emitted from the light emitting layer may be caused to resonate between a first interface constituted by an interface between the first electrode (or a light reflecting layer disposed below the first electrode via the interlayer insulation layer) and the organic layer and a second interface constituted by an interface between the second electrode and the organic layer, and a part of the light may be emitted from the second electrode. In addition, when a distance from a maximum emission position of the light emitting layer to the first interface is represented by L_1 , an optical distance thereof is represented by OL_1 , a distance from the maximum emission position of the light emitting layer to the second interface is represented by L_2 , an optical distance thereof is represented by OL_2 , and m_1 and m_2 each represent an integer, the following formulas (1-1), (1-2), (1-3), and (1-4) are satisfied.

$$0.7\{-\Phi_1/(2\pi)+m_1\}\leq 2\times OL_1/\lambda\leq 1.2\{-\Phi_1/(2\pi)+m_1\} \quad (1-1)$$

$$0.7\{-\Phi_2/(2\pi)+m_2\}\leq 2\times OL_2/\lambda\leq 1.2\{-\Phi_2/(2\pi)+m_2\} \quad (1-2)$$

$$L_1 < L_2 \quad (1-3)$$

$$m_1 < m_2 \quad (1-4)$$

Herein,

[0055] λ : Maximum peak wavelength of a spectrum of light generated in the light emitting layer (or a desired wavelength among wavelengths of light generated in the light emitting layer)

[0056] Φ_1 : Phase shift amount (unit: radian) of light reflected on the first interface

[0057] Provided that $-2\pi < \Phi_1 \leq 0$ is satisfied.

[0058] Φ_2 : Phase shift amount (unit: radian) of light reflected on the second interface

[0059] Provided that $-2\pi < \Phi_2 \leq 0$ is satisfied.

[0060] Herein, $m_1=0$ and $m_2=1$ that can maximize a light extraction efficiency can be satisfied.

[0061] Incidentally, the distance L_1 from the maximum emission position of the light emitting layer to the first interface means an actual distance (physical distance) from the maximum emission position of the light emitting layer to the first interface, and the distance L_2 from the maximum emission position of the light emitting layer to the second interface means an actual distance (physical distance) from the maximum emission position of the light emitting layer to the second interface. In addition, the optical distance is also called an optical path length, and generally means $n \times L$ when a light ray passes through a medium having a refractive index n for a distance L . The same applies to the following description. Therefore, when the average refractive index of the organic layer (or the organic layer and the interlayer insulation layer) is n_{ave} , there is a relationship of

$$OL_1 = L_1 \times n_{ave} \text{ and}$$

$$OL_2 = L_2 \times n_{ave}.$$

Herein, the average refractive index n_{ave} is obtained by summing up a product of the refractive index and the thickness of each layer constituting the organic layer (or the organic layer and the interlayer insulation layer), and dividing the resulting sum by the thickness of the organic layer (or the organic layer and the interlayer insulation layer).

[0062] The first electrode or the light reflecting layer and the second electrode absorb a part of incident light and reflect the rest. Therefore, a phase shift occurs in the reflected light. The phase shift amounts Φ_1 and Φ_2 can be determined by measuring values of a real number part and an imaginary number part of a complex refractive index of a material constituting the first electrode or the light reflecting layer and the second electrode, for example, using an ellipsometer, and performing calculation based on these values (refer to, for example, "Principles of Optic", Max Born and Emil Wolf, 1974 (PERGAMON PRESS)). Note that the refractive index of the organic layer, the interlayer insulation layer, or the like can also be determined by measurement with an ellipsometer.

[0063] As described above, in an organic EL display device having a resonator structure, actually, a red light emitting element constituted by inclusion of a red color filter layer in a white light emitting element causes red light emitted from the light emitting layer to resonate, and emits reddish light (light having a light spectrum peak in a red region) from the second electrode. In addition, the green light emitting element constituted by inclusion of a green

color filter layer in a white light emitting element causes green light emitted from the light emitting layer to resonate, and emits greenish light (light having a light spectrum peak in a green region) from the second electrode. In addition, the blue light emitting element constituted by inclusion of a blue color filter layer in a white light emitting element causes blue light emitted from the light emitting layer to resonate, and emits blueish light (light having a light spectrum peak in a blue region) from the second electrode. That is, it is only required to design each light emitting element by determining a desired wavelength λ (specifically, wavelengths of red light, green light, and blue light) among wavelengths of light generated in the light emitting layer and determining various parameters such as OL_1 and OL_2 in each of the red light emitting element, the green light emitting element, and the blue light emitting element on the basis of formulas (1-2), (1-2), (1-3), and (1-4).

[0064] Examples of a material constituting the light reflecting layer include aluminum, an aluminum alloy (for example, Al—Nd), a Ti/Al laminated structure, chromium (Cr), silver (Ag), and a silver alloy (for example, Ag—Pd—Cu or Ag—Sm—Cu). The light reflecting layer can be formed, for example, by a vapor deposition method including an electron beam vapor deposition method, a hot filament vapor deposition method, and a vacuum vapor deposition method, a sputtering method, a CVD method, and an ion plating method; a plating method (an electroplating method or an electroless plating method); a lift-off method; a laser ablation method; a sol-gel method, or the like.

[0065] In the organic EL display device, the thickness of a hole transport layer (hole supply layer) and the thickness of an electron transport layer (electron supply layer) are desirably substantially equal to each other. Alternatively, the thickness of the electron transport layer (electron supply layer) may be larger than that of the hole transport layer (hole supply layer). As a result, an electron can be supplied sufficiently to the light emitting layer in an amount necessary for a high efficiency at a low driving voltage. That is, by disposing a hole transport layer between the first electrode corresponding to an anode electrode and the light emitting layer, and forming the hole transport layer with a film having a film thickness smaller than the electron transport layer, supply of holes can be increased. Then, this makes it possible to obtain a carrier balance with no excess or deficiency of holes and electrons and a sufficiently large carrier supply amount. Therefore, high emission efficiency can be obtained. In addition, due to no excess or deficiency of holes and electrons, the carrier balance hardly collapses, drive deterioration is suppressed, and an emission lifetime can be prolonged.

[0066] In the display device of the present disclosure or the like, in a form in which one pixel (or sub-pixel) is constituted by one light emitting element (display element), examples of arrangement of a pixel (or sub-pixel) include stripe arrangement, diagonal arrangement, delta arrangement, and rectangle arrangement although not being limited thereto. Furthermore, in a form in which one pixel (or sub-pixel) is constituted by assembly of a plurality of light emitting elements (display elements), examples of arrangement of a pixel (or sub-pixel) include stripe arrangement although not being limited thereto.

[0067] On an outermost surface of the display device (outer surface of the second substrate), an ultraviolet absorb-

ing layer, a contamination preventing layer, a hard coat layer, and an antistatic layer may be formed, or a protective member may be disposed.

[0068] The display device of the present disclosure or the like can be used, for example, as a monitor device constituting a personal computer, or a monitor device incorporated in a television receiver, a mobile phone, a personal digital assistant (PDA), or a game machine. Alternatively, the display device of the present disclosure or the like can be applied to an electronic view finder (EVF) or a head mounted display (HMD).

Example 1

[0069] Example 1 relates to the display device (specifically, organic EL display device) according to the first aspect of the present disclosure. FIG. 1 illustrates a schematic partial cross-sectional view of the display device of Example 1. Note that, in FIG. 1 or FIG. 5 described below, hatching is omitted for the light diffusion layer, the particles, and the transparent material layer. The display device of Example 1 or the display device of Example 2 or 3 described below is an active matrix type display device of color display, and is a top emission type display device. That is, light is emitted via the second electrode.

[0070] That is, the display device of Example 1 or the display device of Example 2 or 3 described below includes a first substrate 11, a second substrate 12, and a plurality of light emitting elements (display elements) 10 located between the first substrate 11 and the second substrate 12 and arranged in a two-dimensional matrix, and emits light via the second substrate 12. Each of the light emitting elements 10 is formed by laminating, from a side of the first substrate, a first electrode 51, an organic layer 70 having a light emitting layer, a second electrode 52, and a sealing layer 15. Organic EL elements which are light emitting elements are arranged in a two-dimensional matrix in a first direction and a second direction extending in a direction orthogonal to the first direction.

[0071] Alternatively, in another expression, the display device of Example 1 or the display device of Example 2 or 3 described below includes the first substrate 11, the second substrate 12, and an image display unit 13 sandwiched by the first substrate 11 and the second substrate 12. In the image display unit 13, the plurality of light emitting elements 10 is arranged in a two-dimensional matrix.

[0072] In addition, in the display device of Example 1, a light diffusion layer 80 containing particles (fine particles) 81 is further formed between the sealing layer 15 and the second substrate 12, and orthographic images of the particles 81 in the light diffusion layer 80 do not overlap each other on the second substrate 12. That is, in the light diffusion layer 80, the particles 81 do not overlap each other, and the particles 81 are arranged in a single layer state and in the closest packed state, or in a random state, or in a state in which a gap is formed. In the display device of Example 1 or the display device of Example 2 or 3 described below, a color filter layer CF is formed between the light diffusion layer 80 or 90 and the second substrate 12, and a light shielding layer (black matrix layer) BM is formed between the color filter layer CF and the color filter layer CF. The color filter layer CF and the light shielding layer BM are formed in contact with the second substrate 12. Therefore, specifically, the light diffusion layer 80 or 90 is formed between the sealing layer 15 and the color filter layer CF.

[0073] Here, each of the particles **81** is spherical. Specifically, each of the particles **81** includes silica (SiO_2) having a diameter of 1×10^{-6} m (1 μm), and has a value of the refractive index n_{11} of 1.46. The wavelength of light emitted from the light emitting layer is 430 nm to 650 nm. The wavelength of the light emitted from the light emitting layer is the maximum wavelength of visible light (specifically, 650 nm). The diameter of each of the particles **81** is $\frac{1}{10}$ or more of the wavelength of the light emitted from the light emitting layer and not more than the wavelength of the light emitted from the light emitting layer. Furthermore, when the thickness of the light diffusion layer **80** is represented by t and the diameter of each of the particles **81** is represented by R , $1 < t/R < 2$ is satisfied. Specifically, the thickness t of the light diffusion layer **80** is 1.5 μm .

[0074] A space between the particles **81** is filled with a transparent material layer **82**. The transparent material layer **82** includes an acrylic resin, and has a value of the refractive index n_{12} of 1.7 to 1.8. $|n_n - n_{12}| \geq 0.1$ is satisfied.

[0075] Furthermore, in the display device of Example 1, area variation of orthographic images of the particles **81** in the light diffusion layer **80** on the second substrate **12** based on an effective area of the light emitting elements **10** (in Example 1, specifically, the area of the color filter layer CF constituting each light emitting element, and the same applies to the following Examples) was within 3% (specifically, 1%). Furthermore, in the display device of Example 1, $S_1/S_0 \leq 0.9$ is satisfied when the total area of the orthographic images of the particles **81** in the light diffusion layer **80** on the second substrate **12** is represented by S_1 , and the effective area of the light emitting elements **10** is represented by S_0 . Specifically, $S_1/S_0 = 0.2$ was satisfied.

[0076] One pixel is constituted by three sub-pixels (three light emitting elements) of a red display sub-pixel SP_R (red light emitting element **10R**), a green display sub-pixel SP_G (green light emitting element **10G**), and a blue display sub-pixel SP_B (blue light emitting element **10B**). The second substrate **12** includes color filter layers CF_R , CF_G , and CF_B . Each color light emitting sub-pixel is constituted by a light emitting element (organic EL element) that emits white light and includes the color filter layers CF_R , CF_G , and CF_B . That is, the light emitting layer itself emits white light as a whole. The red light emitting element (red display element) **10R**, the green light emitting element (green display element) **10G**, and the blue light emitting element (blue display element) **10B** have the same configuration and structure except for the color filter layer CF. In addition, as described above, the light shielding layer (black matrix layer) BM is disposed between the color filter layer CF and the color filter layer CF. The number of pixels is, for example, 1920×1080 . One of the light emitting elements **10** constitutes one sub-pixel, and the number of light emitting elements (specifically, organic EL elements) **10** is three times the number of pixels.

[0077] In the display device of Example 1 or the display device of Example 2 or 3 described below, the first electrode **51** functions as an anode electrode, the second electrode **52** functions as a cathode electrode, and the second electrode **52** includes a transparent conductive material such as ITO. In addition, the second substrate **12** includes a glass substrate. The first electrode **51** is formed on the basis of a combination of a vacuum deposition method and an etching method. A film of the second electrode **52** is formed particularly by a film formation method in which film forming particles

have small energy, such as a vacuum vapor deposition method, and is not patterned. The organic layer **70** is not patterned, either. Furthermore, in the display device of Example 1 or the display device of Example 2 described below, the first substrate **11** includes a glass substrate, and the first electrode **51** includes a light reflecting material, specifically, an Al—Nd alloy or an Al—Ni alloy.

[0078] The first electrode **51** is disposed on an interlayer insulation layer **40** including SiON and formed on the basis of a CVD method. In addition, the interlayer insulation layer **40** covers an organic EL element driving unit formed on the first substrate **11**. The organic EL element driving unit is constituted by a plurality of TFTs (thin film transistors) **20**. The TFTs **20** are electrically connected to the first electrode **51** via a contact plug **26** disposed in the interlayer insulation layer **40**. An actual light emitting portion of the organic layer **70** is surrounded by an insulation layer **60** including SiO_2 . Note that, in the drawings, one TFT **20** is illustrated for one organic EL element driving unit.

[0079] The organic layer **70** having a light emitting layer including an organic light emitting material is disposed as a continuous layer common to all pixels. The organic layer **70** has a laminated structure obtained, for example, by sequentially laminating, from a side of the first electrode, a hole injection layer, a hole transport layer, a light emitting layer (a light emitting layer that generates white light by color mixing, specifically constituted by a red light emitting layer, a green light emitting layer, and a blue emitting layer), and an electron transport layer, and generates white light. Note that there is a case where the red light emitting layer, the green light emitting layer, and the blue light emitting layer cannot be clearly distinguished from one another. The hole injection layer injects holes into the hole transport layer, and includes a hexaazatriphenylene derivative, for example. The hole transport layer transports the holes injected from the hole injection layer to the light emitting layer, and includes 4,4',4"-tris(3-methylphenylphenylamino) triphenylamine (m-MTDATA) or α -naphthylphenyl diamine (α NPD), for example. The red light emitting layer generates red light utilizing an organic EL phenomenon, and is formed by mixing 30% by mass of 2,6-bis[4'-methoxydiphenylamino) styryl]-1,5-dicyanonaphthalene (BSN) with 4,4-bis(2,2-diphenylvinyl) biphenyl (DPVBi), for example. The green light emitting layer generates green light utilizing an organic EL phenomenon, and is formed by mixing 5% by mass of coumarin 6 with DPVBi, for example. The blue light emitting layer generates blue light utilizing an organic EL phenomenon, and is formed by mixing 2.5% by mass of 4,4'-bis [2-{4-(N,N-diphenylamino) phenyl} vinyl]biphenyl (DPAVB) with DPVBi, for example. The electron transport layer transports electrons to the light emitting layer, and includes 8-hydroxyquinoline aluminum (Alq_3), for example. However, the materials constituting the layers are illustrative, and are not limited to these materials. Furthermore, for example, the light emitting layer may be constituted by a blue light emitting layer and a yellow light emitting layer, or may be constituted by a blue light emitting layer and an orange light emitting layer.

[0080] Each of the light emitting elements **10** may have a resonator structure in which the organic layer **70** is a resonance part. In this case, in order to appropriately adjust a distance from a light emitting surface to a reflecting surface (specifically, for example, the first electrode **51** and the second electrode **52**), the thickness of the organic layer

70 is preferably 8×10^{-8} m or more and 5×10^{-7} m or less, and more preferably 1.5×10^{-7} m or more and 3.5×10^{-7} m or less.

[0081] An insulating or conductive protection film 14 (specifically, including a SiO_2 -based material or a SiN -based material, for example) is disposed above the second electrode 52, that is, between the second electrode 52 and the sealing layer (sealing resin layer) 15 in order to prevent moisture from reaching the organic layer 70. The protective film 14 is bonded to the second substrate 12 (more specifically, the light diffusion layer 80) via the sealing layer (sealing resin layer) 15 including, for example, an acrylic adhesive or an epoxy-based adhesive.

[0082] The TFT 20 is constituted by a gate electrode 21 formed on the first substrate 11, a gate insulation layer 22 formed on the first substrate 11 and the gate electrode 21, a source/drain region 24 formed on the gate insulation layer 22, and a channel formation region 23 formed between the source/drain regions 24 so as to face the gate electrode 21.

[0083] Hereinafter, the outline of a method for manufacturing the display device (organic EL display device) of Example 1 will be described.

[0084] The second substrate 12 is prepared. Specifically, the color filter layer CF and the light shielding layer BM are formed on the second substrate 12 by a known method. Then, the light diffusion layer 80 is formed on the color filter layer CF and the light shielding layer BM. Specifically, the light diffusion layer 80 can be formed by a method for applying a photosensitive resin having spherical particles of SiO_2 dispersed therein and curing the photosensitive resin. Thereafter, in order to fill a space between the particles 81, the transparent material layer 82 is formed on the light diffusion layer 80 by a combination of a CVD method and an etching method or a coating method depending on a material constituting the transparent material layer 82. Thereafter, a top surface of the transparent material layer 82 is planarized to planarize the transparent material layer 82.

[0085] [Step-100]

[0086] Meanwhile, a light emitting element driving unit is formed on the first substrate 11 on the basis of a known TFT manufacturing process, and then the interlayer insulation layer 40 is formed on the entire surface on the basis of a CVD method. Then, in a portion of the interlayer insulation layer 40 located above one of the source/drain regions 24 of the TFT 20, a connection hole is formed on the basis of photolithography technology and etching technology. Thereafter, a metal layer is formed on the interlayer insulation layer 40 including the connection hole on the basis of a sputtering method, for example. Subsequently, the metal layer is patterned on the basis of photolithography technology and etching technology, and the first electrode 51 can be thereby formed on the interlayer insulation layer 40. Furthermore, the contact plug 26 can be formed in the interlayer insulation layer 40. The first electrode 51 is separated for each light emitting element.

[0087] [Step-110]

[0088] Thereafter, the insulation layer 60 including SiO_2 is formed on the entire surface on the basis of a CVD method. Thereafter, an opening 61 is formed in a portion of the insulation layer 60 located above the first electrode 51 based on photolithography technology and etching technology, and the first electrode 51 is exposed to a bottom of the opening 61. Examples of a planar shape of the opening 61 include a square shape, a square shape with four corners rounded, a

rectangular shape, a rectangular shape with four corners rounded, a circular shape, and an elliptical shape.

[0089] [Step-120]

[0090] Thereafter, the organic layer 70 is formed on a portion of the first electrode 51 exposed to a bottom of the opening 61 and the insulation layer 60 by a PVD method such as a vacuum vapor deposition method or a sputtering method, or a coating method such as a spin coating method or a die coating method, for example. Subsequently, the second electrode 52 is formed on the entire surface of the organic layer 70 on the basis of a vacuum vapor deposition method, for example. In this way, films of the organic layer 70 and the second electrode 52 can be continuously formed on the first electrode 51, for example, in a vacuum atmosphere. Thereafter, the protective film 14 is formed on the entire surface by a CVD method or a PVD method, for example.

[0091] Incidentally, a lowermost layer of the organic layer 70 may be constituted by a charge injection/transport layer, and at the time of forming the organic layer 70, at least a part of the charge injection/transport layer may be in a discontinuous state (stage-discontinuous state) at an edge 61A of the opening 61 in the insulation layer 60. That is, the charge injection/transport layer is brought into a discontinuous state or in a high resistance state. In addition, as a result, the resistance of the charge injection/transport layer is increased. Therefore, occurrence of a phenomenon that a leakage current flows via the charge injection/transport layer between a first electrode of a certain light emitting element and a second electrode constituting an adjacent light emitting element can be prevented. Incidentally, specifically, the charge injection/transport layer may be constituted by a hole injection layer. In a case where the hole injection layer is not formed but a hole transport layer is formed, the charge injection/transport layer may be constituted by the hole transport layer.

[0092] [Step-140]

[0093] Finally, the protective film 14 is bonded to the light diffusion layer 80 (specifically, the transparent material layer 82) via the sealing layer (sealing resin layer) 15. In this way, the display device illustrated in FIG. 1 can be obtained.

[0094] FIG. 2A illustrates a model diagram when parallel light is incident on one of the particles 81. FIGS. 2B and 3 schematically illustrate behavior of light inside the display device of Example 1. Note that hatching is omitted in FIGS. 2B and 3.

[0095] In the display device of Example 1, each of the particles 81 is regarded as a spherical lens. In addition, as illustrated in FIG. 2A, when it is assumed that a parallel light ray is incident on a spherical lens and is emitted from the spherical lens, a maximum value of an angle formed by an optical axis of the spherical lens and the light ray emitted from the spherical lens (maximum angle) is represented by θ_{max} . Furthermore, an average distance between the second electrode 52 and the light diffusion layer 80 is represented by T, the shortest distance between light emitting elements 10 adjacent to each other is represented by L, the refractive index of a material constituting the second substrate is represented by n_2 , and the refractive index of a medium in contact with the light diffusion layer 80 on a side of the second substrate is represented by n' . Provided that $n' > n_2$ is satisfied. Herein, the color filter layer CF is formed. Therefore, as illustrated in FIG. 2B, when a point where the second electrode 52 intersects with the shortest straight line

connecting an edge of the first electrode **51** constituting a certain light emitting element **10** and an edge Q of the color filter layer CF constituting an adjacent light emitting element adjacent to the certain light emitting element **10** is represented by P, the shortest distance L means the shortest horizontal distance from the point P to the edge Q of the color filter layer constituting the adjacent light emitting element (refer to FIG. 2B). The maximum angle θ_{max} is a value depending on the refractive index of a material constituting the particles **81** and the refractive index of a material constituting the transparent material layer **82**.

[0096] Among light rays emitted from a light emitting layer located near the edge **61A** of the opening **61**, a light ray which is incident on an adjacent light emitting element **10** and which is the shortest light ray incident on the edge Q of the color filter layer CF constituting the adjacent light emitting element **10** (light ray indicated by straight line Ln in FIG. 2B) is assumed. Incidentally, in the following description, in order to simplify discussion, the refractive index of a material constituting the sealing layer (sealing resin layer) **15** and the refractive index of a material constituting the protective film **14** are the same, and the refractive index of a material constituting the transparent material layer **82** is the same as the refractive index of a material constituting the color filter layer CF. An angle formed by a vertical line to the second substrate **12** (the same applies to the following) and this light ray is α . Incidentally, in a case where the refractive index of the material constituting the sealing layer (sealing resin layer) **15** is different from the refractive index of the material constituting the protective film **14**, it is only required to define the angle α considering the thickness and the refractive index of the sealing layer (sealing resin layer) **15**, and the thickness and the refractive index of the protective film **14**. When this light ray is incident on one of the particles **81** and is emitted therefrom, the largest angle formed by one of the emitted light rays and the vertical line is $(\alpha - \theta_{max})$ as illustrated in FIG. 2A. The emitted light having such an angle is referred to as "maximum angle emitted light" for convenience.

[0097] In the maximum angle emitted light passing through the color filter layer CF and incident on the second substrate **12**, when the emitting angle to the second substrate **12** is represented by φ ,

[0098] a relationship of $n' \cdot \sin(\alpha - \theta_{max}) = n_2 \cdot \sin(\varphi)$ (a) is satisfied. Here, when the refractive index of air is represented by n_0 ,

[0099] if the emitting angle φ satisfies $n_2 \cdot \sin(\varphi) \geq n_0$ (b),

[0100] the maximum angle emitted light is totally reflected on an interface between the second substrate **12** and air, and is returned to the second substrate **12**.

[0101] Therefore, $n' \cdot \sin(\alpha - \theta_{max}) \geq n_0$ (c) is derived from formulas (a) and (b). Furthermore, a $\alpha \geq \theta_{max} + \arcsin(n_0/n')$ (d) is derived from formula (c). Provided that $\tan(\alpha) = L/T$ is satisfied.

[0102] As described above, by properly determining the parameters L and T, the refractive indices of materials constituting the particles **81** and the transparent material layer **82**, and the refractive index n' of a medium in contact with the light diffusion layer **80** on a side of the second substrate in order to satisfy formula (d), light emitted from the adjacent light emitting element **10** can be effectively and reliably reduced.

[0103] Specifically, in the display device of Example 1,

[0104] $L = 20 \mu\text{m}$,

[0105] $T = 15 \mu\text{m}$

[0106] the refractive index of the particles **81**: 1.46, and

[0107] the refractive index of the transparent material layer **82**: 1.8 were used.

[0108] Incidentally, depending on light distribution characteristics due to a microcavity effect, a required color gamut, and the like, there is a case where there is no problem even if some color mixing occurs. Therefore, regarding formula (d), it is only required to almost satisfy the relationship of formula (d). Specifically, a value obtained by multiplying the right side of formula (d) by 0.9 may be used.

$$\alpha \geq 0.9 \{ \theta_{max} + \arcsin(n_0/n') \} \quad (d')$$

[0109] In the example illustrated in FIG. 3, unlike the example illustrated in FIG. 2B, the color filter layer is not formed, and the light diffusion layer **80** is directly formed on the second substrate **12**. In this case, a medium in contact with the light diffusion layer **80** on a side of the second substrate is the second substrate **12**. In addition, also in this case, formula (d) is satisfied. Therefore, by properly determining the parameters L and T, the refractive indices of materials constituting the particles **81** and the transparent material layer **82**, and the refractive index n' of a material constituting the second substrate **12** in order to satisfy formula (d) or (d'), light emitted from the adjacent light emitting element **10** can be effectively and reliably reduced.

[0110] <Display Device of Comparative Example 1A>

[0111] A display device having the same configuration and structure as in Example 1 except that a light diffusion layer was not formed, obtained by bonding an anti-reflection (AR) film on an outer surface of the second substrate, was manufactured as a display device of Comparative Example 1A.

[0112] <Display Device of Comparative Example 1B>

[0113] A display device having the same configuration and structure as in Example 1 except that a light diffusion layer was not formed, obtained by bonding a circular polarization plate on an outer surface of the second substrate, was manufactured as a display device of Comparative Example 1B.

[0114] <Display Device of Comparative Example 1C>

[0115] A display device having the same configuration and structure as in Example 1 except that a light diffusion layer was not formed, obtained by bonding an anti-glare (AG) film on an outer surface of the second substrate, was manufactured as a display device of Comparative Example 1C.

[0116] In addition, using the display device of Comparative Example 1A as a reference, luminous efficiency, bleeding/glare feeling, and a state of reflection were examined in the display device of Example 1, the display device of Comparative Example 1B, and the display device of Comparative Example 1C. Results are indicated in Table 1 below. Note that bleeding/glare feeling is caused by light emitted from an adjacent light emitting element, and reflection is caused by a reflection component. In Table 1, "○" means very good, "o" means good, and "x" means poor.

TABLE 1

	Example 1	Comparative Example 1B	Comparative Example 1C	Comparative Example 1A
Luminous efficiency	0.90	0.42	0.95	1.00
Bleeding/glare feeling	○	⊙	X	⊙
Reflection	○	⊙	○	X

[0117] The display device of Comparative Example 1A had no bleeding/glare feeling and had a very good result on bleeding/glare feeling, but had intense reflection and had a poor result on reflection. The display device of Comparative Example 1B had no bleeding/glare feeling or no reflection and had very good results on bleeding/glare feeling and reflection, but had low luminous efficiency. The display device of Comparative Example 1C had no reflection and had a good result on reflection, but had intense bleeding/glare feeling and had a poor result on bleeding/glare feeling. [0118] The display device of Example 1 had no reflection or no bleeding/glare feeling and had good results on reflection and bleeding/glare feeling, and had high luminous efficiency. The display device of Example 1 is a display device with balanced characteristics.

[0119] As described above, in the display device of Example 1, the light diffusion layer containing particles (fine particles) is formed between the sealing layer and the second substrate, and therefore a reflection component can be reduced, and reflection can be reduced. In addition, orthographic images of the particles in the light diffusion layer do not overlap each other on the second substrate, and therefore each of the particles functions as a kind of lens. As a result, when light emitted from a certain light emitting element enters an adjacent light emitting element and is emitted from the adjacent light emitting element to an outside, a ratio of the light totally reflected on an outer surface of the second substrate and returning to the adjacent light emitting element is increased. That is, the light emitted from the adjacent light emitting element can be reduced. Therefore, it is possible to suppress occurrence of deterioration in quality of a displayed image, such as image blur, bleeding, or resolution reduction. In addition, color mixing in an adjacent light emitting element can be suppressed. As a result, a wide color gamut can be realized, and a display device with high quality and low power consumption can be provided.

Example 2

[0120] Example 2 relates to the display device according to the second aspect of the present disclosure. FIG. 4 illustrates a schematic partial cross-sectional view of the display device of Example 2. Note that, in FIG. 4 or FIG. 6 described below, hatching is omitted for the light diffusion layer, the flat portion, and the flat portion. In the display device of Example 2, the light diffusion layer 90 is formed between the sealing layer 15 and the second substrate 12, and the light diffusion layer 90 includes a flat portion 91 and a plurality of protruding portions 92 each constituted by a part of a spherical surface protruding from the flat portion 91. Specifically, each of the protruding portions 92 has a hemispherical shape.

[0121] In Example 2, when each of the protruding portions 92 is regarded as a part of a spherical lens, the above formula (c) or (d) and (d') are satisfied. Furthermore, the diameter of

a part of a spherical surface constituting each of the protruding portions 92 is $\frac{1}{10}$ or more of the wavelength of light emitted from the light emitting layer and is not more than the wavelength of the light emitted from the light emitting layer. Here, the wavelength of the light emitted from the light emitting layer is similar to that in Example 1, and the diameter of a part of a spherical surface constituting each of the protruding portions 92 is 1.5 μm .

[0122] Furthermore, in the light diffusion layer 90 of the display device of Example 2, a material constituting the flat portion 91 and the protruding portions 92 includes SiO_2 . In the light diffusion layer 90 in the display device of Example 2, the protruding portions 92 are filled with a transparent material layer 93. A material constituting the transparent material layer 93 includes an acrylic resin. When the refractive index of a material constituting the flat portion and the protruding portions is represented by n_{21} and the refractive index of a material constituting the transparent material layer is represented by n_{22} ,

[0123] $|n_{21} - n_{22}| \geq 0.1$ is satisfied. Here, $n_{21} = 1.46$, and

[0124] $n_{22} = 1.8$ are satisfied.

[0125] In the display device of Example 2, area variation of the protruding portions 92 based on the effective area of the light emitting elements 10 is within 3%, specifically, 1%. By setting the area variation within such a range, it is possible to suppress a diffraction pattern due to regularity of the protruding portions 92, occurrence of glare, and the like. Furthermore, when the total area of the protruding portions 92 is represented by S_1' and the effective area of the light emitting elements 10 is represented by S_0 , $S_1'/S_0 \leq 0.9$ is satisfied. Specifically, $S_1'/S_0 = 0.2$ is satisfied.

[0126] In the light diffusion layer 90 in the display device of Example 2, the flat portion 91 and the protruding portions 92 are formed specifically by a well-known method for forming a microlens, more specifically by forming a hemispherical resist layer on a material layer constituting the light diffusion layer 90, for example, by a well-known method, and then etching back the material layer constituting the light diffusion layer 90 and the resist layer.

[0127] The configuration and structure of the display device of Example 2 can be similar to those of the display device of Example 1 except for the configuration and structure of the light diffusion layer 90 described above, and therefore detailed description will be omitted.

[0128] In the display device of Example 2, the light diffusion layer including the flat portion and the plurality of protruding portions is formed between the sealing layer and the second substrate, and therefore a reflection component can be reduced, and reflection can be reduced. In addition, the light diffusion layer includes the flat portion and the plurality of protruding portions each constituted by a part of a spherical surface, and therefore each of the protruding portions functions as a kind of lens. As a result, when light emitted from a certain light emitting element enters an adjacent light emitting element and is emitted from the adjacent light emitting element to an outside, a ratio of the light totally reflected on an outer surface of the second substrate and returning to the adjacent light emitting element is increased. That is, the light emitted from the adjacent light emitting element can be reduced. Therefore, it is possible to suppress occurrence of deterioration in quality of a displayed image, such as image blur, bleeding, or resolution reduction. In addition, color mixing in an adjacent light emitting element can be suppressed. As a result, a wide color

gamut can be realized, and a display device with high quality and low power consumption can be provided.

Example 3

[0129] Example 3 is a modification of Examples 1 and 2. In Example 3, a light reflecting layer is formed below a first electrode via an interlayer insulation layer, and a resonator structure is formed between the light reflecting layer and a second electrode. FIG. 5 illustrates a schematic partial cross-sectional view of the display device of Example 3 obtained by modifying the display device of Example 1. In addition, FIG. 6 illustrates a schematic partial cross-sectional view of the display device of Example 3 obtained by modifying the display device of Example 2.

[0130] Each of the light emitting element 10 of Example 3 includes a lower layer/interlayer insulation layer 31, a light reflecting layer 37 formed on the lower layer/interlayer insulation layer 31, an upper layer/interlayer insulation layer 32 covering the lower layer/interlayer insulation layer 31 and the light reflecting layer 37, a first electrode 51 formed on the upper layer/interlayer insulation layer 32, an insulation layer 60 formed at least on a region of the upper layer/interlayer insulation layer 32 on which the first electrode 51 is not formed, an organic layer 70 formed over the insulation layer 60 from above the first electrode 51 and having a light emitting layer including an organic light emitting material, and a second electrode 52 formed on the organic layer 70.

[0131] In addition, the display device of Example 3 is a display device in which a plurality of pixels each constituted by a first light emitting element 10R, a second light emitting element 10G, and a third light emitting element 10B is arranged in a two-dimensional matrix. The plurality of pixels has a laminated structure obtained by sequentially laminating a lowermost layer/interlayer insulation layer 33, a first interlayer insulation layer 34, a second interlayer insulation layer 35, and an uppermost layer/interlayer insulation layer 36. In addition, each of the light emitting elements 10R, 10G, and 10B includes the first electrode 51 formed on the uppermost layer/interlayer insulation layer 36, the insulation layer 60 formed at least on a region of the uppermost layer/interlayer insulation layer 36 on which the first electrode 51 is not formed, the organic layer 70 formed over the insulation layer 60 from above the first electrode 51 and having a light emitting layer including an organic light emitting material, and the second electrode 52 formed on the organic layer 70. The first light emitting element 10R includes a first light reflecting layer 38R formed between the lowermost layer/interlayer insulation layer 33 and the first interlayer insulation layer 34. The second light emitting element 10G includes a second light reflecting layer 38G formed between the first interlayer insulation layer 34 and the second interlayer insulation layer 35. The third light emitting element 10B includes a third light reflecting layer 38B formed between the second interlayer insulation layer 35 and the uppermost layer/interlayer insulation layer 36.

[0132] Note that the first interlayer insulation layer 34, the second interlayer insulation layer 35, and the uppermost layer/interlayer insulation layer 36 are collectively referred to as an interlayer insulation layer/laminated structure 30.

[0133] Alternatively, in another expression, the display device of Example 3 includes the first substrate 11, the second substrate 12, and the image display unit 13 sandwiched by the first substrate 11 and the second substrate 12.

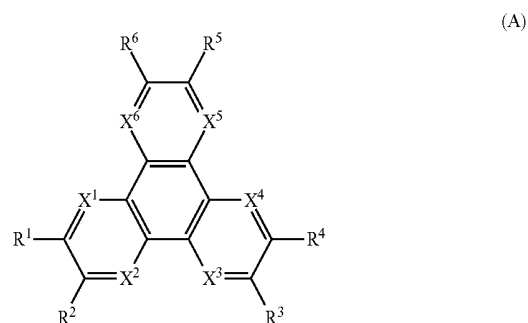
In the image display unit 13, the plurality of light emitting elements 10 (10R, 10G, and 10B) of Example 3 is arranged in a two-dimensional matrix. Herein, the light emitting elements are formed on a side of the first substrate.

[0134] The first electrode 51 includes ITO. The light reflecting layer 37 (first light reflecting layer 38R, second light reflecting layer 38G, and third light reflecting layer 38B) has a laminated structure of titanium (Ti)/aluminum (Al). Furthermore, the first substrate 11 includes a silicon semiconductor substrate, and the second substrate 12 includes a glass substrate. In addition, a MOSFET is formed on the silicon semiconductor substrate in place of a TFT.

[0135] In Example 3, the organic layer 70 may include the materials exemplified in Example 1, or may include materials exemplified below. Also in Example 1, the organic layer 70 may include materials exemplified below.

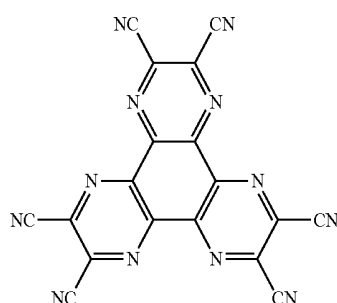
[0136] That is, in Example 3, the organic layer 70 has a laminated structure of a hole injection layer (HIL), a hole transport layer (HTL), a light emitting layer, an electron transport layer (ETL), and an electron injection layer (EIL). The light emitting layer is constituted by at least two light emitting layers that emit different colors, and light emitted from the organic layer 70 is white. Specifically, the light emitting layer has a structure in which three layers of a red light emitting layer that emits red light, a green light emitting layer that emits green light, and a blue light emitting layer that emits blue light are laminated. The red light emitting element 10R, the green light emitting element 10G, and the blue light emitting element 10B have the same configuration and structure except for the color filters and the positions of the light reflecting layer.

[0137] The hole injection layer increases a hole injection efficiency, functions as a buffer layer for preventing leakage, and has a thickness of about 2 nm to 10 nm, for example. The hole injection layer includes a hexaazatriphenylene derivative represented by the following formula (A) or (B), for example.



[0138] Herein, R¹ to R⁶ each independently represent a substituent selected from a hydrogen atom, a halogen atom, a hydroxy group, an amino group, an arylamino group, a substituted or unsubstituted carbonyl group having 20 or less carbon atoms, a substituted or unsubstituted carbonyl ester group having 20 or less carbon atoms, a substituted or unsubstituted alkyl group having 20 or less carbon atoms, a substituted or unsubstituted alkenyl group having 20 or less carbon atoms, a substituted or unsubstituted alkoxy group having 20 or less carbon atoms, a substituted or unsubstituted aryl group having 30 or less carbon atoms, a substituted or unsubstituted heterocyclic group having 30 or less

carbon atoms, a nitrile group, a cyano group, a nitro group, and a silyl group, and adjacent R^m's (m=1 to 6) may be bonded to each other via a cyclic structure. In addition, X¹ to X⁶ each independently represent a carbon atom or a nitrogen atom.



(B)

[0139] The hole transport layer is a layer that increases a hole transport efficiency to the light emitting layer. When an electric field is applied to the light emitting layer, recombination of electrons and holes occurs to generate light. The electron transport layer is a layer that increases an electron transport efficiency to the light emitting layer, and the electron injection layer is a layer that increases an electron injection efficiency to the light emitting layer.

[0140] The hole transport layer includes 4,4',4''-tris(3-methylphenylphenylamino) triphenylamine <m-MTDATA> or α -naphthylphenyl diamine < α -NPD> having a thickness of about 40 nm, for example.

[0141] The light emitting layer is a light emitting layer that generates white light by color mixing, and is formed by laminating a red light emitting layer, a green light emitting layer, and a blue light emitting layer as described above, for example.

[0142] When an electric field is applied to the red light emitting layer, a part of holes injected from the first electrode 51 and a part of electrons injected from the second electrode 52 are recombined to generate red light. Such a red light emitting layer contains at least one kind of material among a red light emitting material, a hole transport material, an electron transport material, and a both charge transport material, for example. The red light emitting material may be a fluorescent material or a phosphorescent material. The red light emitting layer having a thickness of about 5 nm is formed by mixing 30% by mass of 2,6-bis[(4'-methoxydiphenylamino) styryl]-1,5-dicyanonaphthalene <BSN> with 4,4-bis(2,2-diphenylvinyl) biphenyl <DPVBi>, for example.

[0143] When an electric field is applied to the green light emitting layer, a part of holes injected from the first electrode 51 and a part of electrons injected from the second electrode 52 are recombined to generate green light. Such a green light emitting layer contains at least one kind of material among a green light emitting material, a hole transport material, an electron transport material, and a both charge transport material, for example. The green light emitting material may be a fluorescent material or a phosphorescent material. The green light emitting layer having a thickness of about 10 nm is formed by mixing 5% by mass of coumarin 6 with DPVBi, for example.

[0144] When an electric field is applied to the blue light emitting layer, a part of holes injected from the first electrode 51 and a part of electrons injected from the second electrode 52 are recombined to generate blue light. Such a blue light emitting layer contains at least one kind of material among a blue light emitting material, a hole transport material, an electron transport material, and a both charge transport material, for example. The blue light emitting material may be a fluorescent material or a phosphorescent material. The blue light emitting layer having a thickness of about 30 nm is formed by mixing 2.5% by mass of 4,4'-bis [2-{4-(N, N-diphenylamino) phenyl} vinyl]biphenyl <DPAVBi> with DPVBi, for example.

[0145] The electron transport layer having a thickness of about 20 nm includes 8-hydroxyquinoline aluminum <Alq3>, for example. The electron injection layer having a thickness of about 0.3 nm includes LiF or Li₂O, for example.

[0146] The lowermost layer/interlayer insulation layer 33, the interlayer insulation layer/laminated structure 30, the organic layer 70, and the second electrode 52 are common in the plurality of light emitting elements. That is, the lowermost layer/interlayer insulation layer 33, the interlayer insulation layer/laminated structure 30, the organic layer 70, and the second electrode 52 are not patterned and are in a so-called solid film state. As described above, by forming a solid film of a light emitting layer common in all the light emitting elements without forming the light emitting layer separately for each light emitting element (patterning formation), the light emitting elements can be also applied to a small and high-resolution display device having a field angle of several inches or less and a pixel pitch of several tens of micrometers or less, for example.

[0147] Each of the light emitting elements 10 has a resonator structure in which the organic layer 70 is a resonance part. Incidentally, in order to appropriately adjust a distance from a light emitting surface to a reflecting surface (specifically, a distance from a light emitting surface to the light reflecting layer 37 and the second electrode 52), the thickness of the organic layer 70 is preferably 8×10^{-8} m or more and 5×10^{-7} m or less, and more preferably 1.5×10^{-7} m or more and 3.5×10^{-7} m or less. In an organic EL display device having a resonator structure, actually, the red light emitting element 10R causes red light emitted from the light emitting layer to resonate, and emits reddish light (light having a light spectrum peak in a red region) from the second electrode 52. In addition, the green light emitting element 10G causes green light emitted from the light emitting layer to resonate, and emits greenish light (light having a light spectrum peak in a green region) from the second electrode 52. Furthermore, the blue light emitting element 10B causes blue light emitted from the light emitting layer to resonate, and emits bluish light (light having a light spectrum peak in a blue region) from the second electrode 52.

[0148] In Example 3, a transistor (specifically, for example, a MOSFET) 120 formed on a silicon semiconductor substrate (first substrate 11) is disposed under the lower layer/interlayer insulation layer 31 (lowermost layer/interlayer insulation layer 33). In addition, the first electrode 51 and the transistor 120 formed on the silicon semiconductor substrate (first substrate 11) are connected to each other via the contact hole (contact plug) 26 formed in the lowermost layer/interlayer insulation layer 33 and the interlayer insulation layer/laminated structure 30. Herein, the transistor

120 includes a MOSFET is constituted by a gate electrode 121, a gate insulation layer 122, a channel formation region 123, and a source/drain region 124. An element isolation region 125 is formed between the transistors 120, and the transistors 120 are thereby separated from each other.

[0149] The configuration and structure of the display device of Example 3 can be similar to those of the display devices of Examples 1 and 2 except for the above points, and therefore detailed description will be omitted.

[0150] Hitherto, the display device of the present disclosure has been described on the basis of preferable Examples. However, the display device of the present disclosure is not limited to these Examples. The configurations and structures of the display device and the light emitting element described in Examples, various materials constituting the display devices and the light emitting elements, the methods for manufacturing the display devices and the light emitting elements, and the like are illustrative and can be changed appropriately. The diameter of each of the particles and each of the protruding portions constituting the light diffusion layer may be different among the red light emitting element, the green light emitting element, and the blue light emitting element. The number of particles or protrusions per effective area of the light emitting elements may be different among the red light emitting element, the green light emitting element, and the blue light emitting element. Furthermore, the shape of each of the protruding portions may be varied depending on the position of the light emitting element. In Examples, one pixel is constituted exclusively by three sub-pixels formed by a combination of a white light emitting element and a color filter layer. However, one pixel may be formed by four sub-pixels obtained by adding a light emitting element that emits white light. Alternatively, one pixel may be constituted by three sub-pixels (light emitting elements) of a sub-pixel having a red light emitting layer and constituted by a light emitting element that emits red light, a sub-pixel having a green light emitting layer and constituted by a light emitting element that emits green light, a sub-pixel having a blue light emitting layer and constituted by a light emitting element that emits blue light, or may be constituted by four sub-pixels (light emitting elements) obtained by adding a sub-pixel constituted by a light emitting element that emits white light (or a light emitting element that emits complementary color light).

[0151] In Examples, the description has been made on the basis of the top emission type display device that emits light from the second substrate. However, a bottom emission type display device that emits light from the first substrate may be used. Furthermore, the color filter layer is disposed on the second substrate. However, a display device having an on-chip color filter (OCCF) structure in which the color filter layer is disposed on the first substrate may be used alternatively. In addition, the description has been made on the basis of the spherical (truly spherical) particles. However, a particle having an aspheric surface such as a spheroid can be used. In this case, “T” of formula $\tan(\alpha)=L/T$ only needs to be defined on the basis of a long axis, and a value or a formula relating to the maximum angle θ_{max} only needs to be defined on the basis of a short axis.

[0152] Note that the present disclosure may have the following configurations.

[0153] [A01] <<Display Device: First Aspect>>

[0154] A display device including:

[0155] a first substrate; a second substrate; and

[0156] a plurality of light emitting elements located between the first substrate and the second substrate and arranged in a two-dimensional matrix, the display device emitting light via the second substrate, in which

[0157] each of the light emitting elements is formed by laminating, from a side of the first substrate, a first electrode, an organic layer having a light emitting layer, a second electrode, and a sealing layer,

[0158] a light diffusion layer including particles is formed between the sealing layer and the second substrate, and

[0159] orthographic images of the particles in the light diffusion layer do not overlap each other on the second substrate.

[0160] [A02] The display device according to [A01], in which

[0161] each of the particles is spherical,

[0162] when each of the particles is regarded as a spherical lens and a parallel light ray is incident on the spherical lens and is emitted from the spherical lens, if a maximum value of an angle formed by an optical axis of the spherical lens and the light ray emitted from the spherical lens is represented by θ_{max} , an average distance between the second electrode and the light diffusion layer is represented by T, the shortest distance between light emitting elements adjacent to each other is represented by L, a refractive index of a medium in contact with the light diffusion layer on a side of the second substrate is represented by n', and a refractive index of air is represented by n_0 ,

[0163] $\alpha \geq \theta_{max} + \arcsin(n_0/n')$ is satisfied,

[0164] provided that $\tan(\alpha)=L/T$ is satisfied.

[0165] [A03] The display device according to [A02], in which

[0166] $\alpha \geq 0.9 \{ \theta_{max} + \arcsin(n_0/n') \}$ is satisfied.

[0167] [A04] The display device according to any one of [A01] to [A03], in which

[0168] each of the particles is spherical, and

[0169] a diameter of each of the particles is $\frac{1}{10}$ or more of a wavelength of light emitted from the light emitting layer.

[0170] [A05] The display device according to any one of [A01] to [A04], in which

[0171] when a thickness of the light diffusion layer is represented by t and a diameter of each of the particles is represented by R,

[0172] $1 < t/R < 2$ is satisfied.

[0173] [A06] The display device according to any one of [A01] to [A05], in which

[0174] area variation of orthographic images of the particles in the light diffusion layer on the second substrate based on an effective area of the light emitting elements is within 3%.

[0175] [A07] The display device according to any one of [A01] to [A06], in which

[0176] when a total area of orthographic images of the particles in the light diffusion layer on the second substrate is represented by S_1 , and an effective area of the light emitting elements is represented by S_0 ,

[0177] $S_1/S_0 \leq 0.9$ is satisfied.

[0178] [A08] The display device according to any one of [A01] to [A07], in which a color filter layer is formed between the light diffusion layer and the second substrate,

and a light shielding layer is formed between the color filter layer and the color filter layer.

[0179] [B01] <<Display Device: Second Aspect>>

[0180] A display device including:

[0181] a first substrate; a second substrate; and

[0182] a plurality of light emitting elements located between the first substrate and the second substrate and arranged in a two-dimensional matrix, the display device emitting light via the second substrate, in which

[0183] each of the light emitting elements is formed by laminating, from a side of the first substrate, a first electrode, an organic layer having a light emitting layer, a second electrode, and a sealing layer,

[0184] a light diffusion layer is formed between the sealing layer and the second substrate, and

[0185] the light diffusion layer includes a flat portion and a plurality of protruding portions each constituted by a part of a spherical surface protruding from the flat portion.

[0186] [B02] The display device according to [B01], in which

[0187] when each of the protruding portions is regarded as a part of a spherical lens and a parallel light ray is incident on the spherical lens and is emitted from the spherical lens, if a maximum value of an angle formed by an optical axis of the spherical lens and the light ray emitted from the spherical lens is represented by θ_{max} , an average distance between the second electrode and the light diffusion layer is represented by T, the shortest distance between light emitting elements adjacent to each other is represented by L, a refractive index of a medium in contact with the light diffusion layer on a side of the second substrate is represented by n' , and a refractive index of air is represented by n_0 ,

[0188] $\alpha \geq \theta_{max} + \arcsin(n_0/n')$ is satisfied,

[0189] provided that $\tan(\alpha) = L/T$ is satisfied.

[0190] [B03] The display device according to [B02], in which

[0191] $\alpha \geq 0.9 \{ \theta_{max} + \arcsin(n_0/n') \}$ is satisfied.

[0192] [B04] The display device according to any one of [B01] to [B03], in which

[0193] a diameter of a part of the spherical surface constituting each of the protruding portions is $1/10$ or more of a wavelength of light emitted from the light emitting layer.

[0194] [B05] The display device according to [B04], in which a diameter of a part of the spherical surface constituting each of the protruding portions is not more than a wavelength of light emitted from the light emitting layer.

[0195] [B06] The display device according to any one of [B01] to [B04], in which area variation of the protruding portions based on an effective area of the light emitting elements is within 3%.

[0196] [B07] The display device according to any one of [B01] to [B06], in which

[0197] when a total area of the protruding portions is represented by S_1' , and an effective area of the light emitting elements is represented by S_0 ,

[0198] $S_1'/S_0 \leq 0.9$ is satisfied.

[0199] [B08] The display device according to any one of [B01] to [B07], in which a color filter layer is formed between the light diffusion layer and the second substrate, and a light shielding layer is formed between the color filter layer and the color filter layer.

REFERENCE SIGNS LIST

- [0200] 10 Light emitting element (display element)
- [0201] 10R Red light emitting element (first light emitting element)
- [0202] 10G Green light emitting element (second light emitting element)
- [0203] 10B Blue light emitting element (third light emitting element)
- [0204] SP_R Red display sub-pixel
- [0205] SP_G Green display sub-pixel
- [0206] SP_B Blue display sub-pixel
- [0207] 11 First substrate
- [0208] 12 Second substrate
- [0209] 13 Image display unit
- [0210] 14 Protective film
- [0211] 15 Sealing layer (sealing resin layer)
- [0212] 20 Thin film transistor (TFT)
- [0213] 120 MOSFET
- [0214] 21, 121 Gate electrode
- [0215] 22, 122 Gate insulation layer
- [0216] 23, 123 Channel formation region
- [0217] 24, 124 Source/drain region
- [0218] 125 Element isolation region
- [0219] 26 Contact hole (contact plug)
- [0220] 30 Interlayer insulation layer/laminated structure
- [0221] 31 Lower layer/interlayer insulation layer
- [0222] 32 Upper layer/interlayer insulation layer
- [0223] 33 Lowermost layer/interlayer insulation layer
- [0224] 34 First interlayer insulation layer
- [0225] 35 Second interlayer insulation layer
- [0226] 36 Uppermost layer/interlayer insulation layer
- [0227] 37 Light reflecting layer
- [0228] 38R First light reflecting layer
- [0229] 38G Second light reflecting layer
- [0230] 38B Third light reflecting layer
- [0231] 40 Interlayer insulation layer
- [0232] 51 First electrode
- [0233] 52 Second electrode
- [0234] 60 Insulation layer
- [0235] 61 Opening
- [0236] 61A Edge of opening
- [0237] 70 Organic layer
- [0238] 81 Particle
- [0239] 80 Light diffusion layer
- [0240] 82 Transparent material layer
- [0241] 90 Light diffusion layer
- [0242] 91 Flat portion
- [0243] 92 Protruding portion
- [0244] 93 Transparent material layer
- [0245] CF, CF_R , CF_G , CF_B Color filter
- [0246] BM Light shielding layer (black matrix layer)

1. A display device comprising:

a first substrate; a second substrate; and

a plurality of light emitting elements located between the first substrate and the second substrate and arranged in a two-dimensional matrix, the display device emitting light via the second substrate, wherein

each of the light emitting elements is formed by laminating, from a side of the first substrate, a first electrode, an organic layer having a light emitting layer, a second electrode, and a sealing layer,

a light diffusion layer including particles is formed between the sealing layer and the second substrate, and

orthographic images of the particles in the light diffusion layer do not overlap each other on the second substrate.

2. The display device according to claim 1, wherein each of the particles is spherical,

when each of the particles is regarded as a spherical lens and a parallel light ray is incident on the spherical lens and is emitted from the spherical lens, if a maximum value of an angle formed by an optical axis of the spherical lens and the light ray emitted from the spherical lens is represented by θ_{max} , an average distance between the second electrode and the light diffusion layer is represented by T, a shortest distance between light emitting elements adjacent to each other is represented by L, a refractive index of a medium in contact with the light diffusion layer on a side of the second substrate is represented by n' , and a refractive index of air is represented by n_0 ,

$\alpha \geq \theta_{max} + \arcsin(n_0/n')$ is satisfied, provided that $\tan(\alpha) = L/T$ is satisfied.

3. The display device according to claim 2, wherein $\alpha \geq 0.9 \{ \theta_{max} + \arcsin(n_0/n') \}$ is satisfied.

4. The display device according to claim 1, wherein each of the particles is spherical, and a diameter of each of the particles is $1/10$ or more of a wavelength of light emitted from the light emitting layer.

5. The display device according to claim 1, wherein when a thickness of the light diffusion layer is represented by t and a diameter of each of the particles is represented by R,

$1 < t/R < 2$ is satisfied.

6. The display device according to claim 1, wherein area variation of orthographic images of the particles in the light diffusion layer on the second substrate based on an effective area of the light emitting elements is within 3%.

7. The display device according to claim 1, wherein when a total area of orthographic images of the particles in the light diffusion layer on the second substrate is represented by S_1 , and an effective area of the light emitting elements is represented by S_0 ,

$S_1/S_0 \leq 0.9$ is satisfied.

8. The display device according to claim 1, wherein a color filter layer is formed between the light diffusion layer and the second substrate, and a light shielding layer is formed between the color filter layer and the color filter layer.

9. A display device comprising:

a first substrate; a second substrate; and a plurality of light emitting elements located between the first substrate and the second substrate and arranged in

a two-dimensional matrix, the display device emitting light via the second substrate, wherein

each of the light emitting elements is formed by laminating, from a side of the first substrate, a first electrode, an organic layer having a light emitting layer, a second electrode, and a sealing layer,

a light diffusion layer is formed between the sealing layer and the second substrate, and

the light diffusion layer includes a flat portion and a plurality of protruding portions each constituted by a part of a spherical surface protruding from the flat portion.

10. The display device according to claim 9, wherein when each of the protruding portions is regarded as a part of a spherical lens, and a parallel light ray is incident on the spherical lens and is emitted from the spherical lens, if a maximum value of an angle formed by an optical axis of the spherical lens and the light ray emitted from the spherical lens is represented by θ_{max} , an average distance between the second electrode and the light diffusion layer is represented by T, a shortest distance between light emitting elements adjacent to each other is represented by L, a refractive index of a medium in contact with the light diffusion layer on a side of the second substrate is represented by n' , and a refractive index of air is represented by n_0 ,

$\alpha \geq \theta_{max} + \arcsin(n_0/n')$ is satisfied, provided that $\tan(\alpha) = L/T$ is satisfied.

11. The display device according to claim 10, wherein $\alpha \geq 0.9 \{ \theta_{max} + \arcsin(n_0/n') \}$ is satisfied.

12. The display device according to claim 9, wherein a diameter of a part of the spherical surface constituting each of the protruding portions is $1/10$ or more of a wavelength of light emitted from the light emitting layer.

13. The display device according to claim 12, wherein a diameter of a part of the spherical surface constituting each of the protruding portions is not more than a wavelength of light emitted from the light emitting layer.

14. The display device according to claim 9, wherein area variation of the protruding portions based on an effective area of the light emitting elements is within 3%.

15. The display device according to claim 9, wherein when a total area of the protruding portions is represented by S_1' , and an effective area of the light emitting elements is represented by S_0 ,

$S_1'/S_0 \leq 0.9$ is satisfied.

16. The display device according to claim 9, wherein a color filter layer is formed between the light diffusion layer and the second substrate, and a light shielding layer is formed between the color filter layer and the color filter layer.

* * * * *

专利名称(译)	显示装置		
公开(公告)号	US20200058888A1	公开(公告)日	2020-02-20
申请号	US15/746929	申请日	2016-05-25
[标]申请(专利权)人(译)	索尼公司		
申请(专利权)人(译)	索尼公司		
当前申请(专利权)人(译)	索尼公司		
[标]发明人	SUGIYAMA KOUHEI FUKUDA TOSHIHIRO TANAKA SHINICHI		
发明人	SUGIYAMA, KOUHEI FUKUDA, TOSHIHIRO TANAKA, SHINICHI		
IPC分类号	H01L51/50 H01L51/52		
CPC分类号	H01L51/502 H01L51/524 H01L51/5203 H01L51/5275 H01L51/5268 H01L51/5284 G02B5/02 G02B5/20 G09F9/30 H01L27/322 H01L51/0024 H01L51/5265 H01L2251/5315 H05B33/02 H05B33/04 H05B33/12		
优先权	2015147359 2015-07-27 JP		
外部链接	Espacenet USPTO		

摘要(译)

显示装置包括第一基板11，第二基板12和多个发光元件10。经由第二基板12发射光。每个发光元件10通过从第一基板的一侧层压第一电极51，具有发光层的有机层70，第二电极52和硅而形成。密封层15。在密封层15和第二基板12之间形成包含微粒81的光扩散层80。光扩散层80中的微粒81的正交图像在第二基板12上彼此不重叠。可选地，光扩散层形成在密封层和第二基板之间，并且光扩散层包括平坦部分和多个突出部分，每个突出部分由从平坦部分突出的球形表面的一部分构成。

